

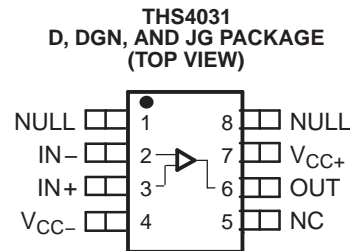
100-MHz LOW-NOISE HIGH-SPEED AMPLIFIERS

FEATURES

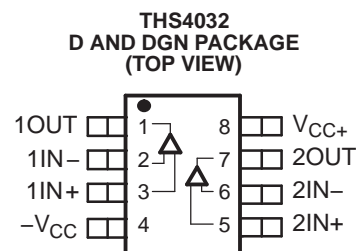
- **Ultralow 1.6-nV/ $\sqrt{\text{Hz}}$ Voltage Noise**
- **High Speed:**
 - 100-MHz Bandwidth [$G = 2$ (-1), -3 dB]
 - 100-V/ μs Slew Rate
- **Very Low Distortion**
 - THD = -72 dBc ($f = 1$ MHz, $R_L = 150 \Omega$)
 - THD = -90 dBc ($f = 1$ MHz, $R_L = 1 \text{ k}\Omega$)
- **Low 0.5-mV (Typ) Input Offset Voltage**
- **90-mA Output Current Drive (Typical)**
- **± 5 V to ± 15 V Typical Operation**
- **Available in Standard SOIC, MSOP PowerPAD™, JG, or FK Package**
- **Evaluation Module Available**

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

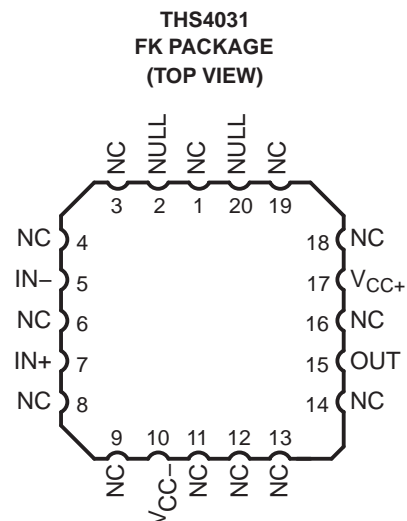
- **Controlled Baseline**
- **One Assembly/Test Site**
- **One Fabrication Site**
- **Available in Military (-55°C/125°C) Temperature Range⁽¹⁾**
- **Extended Product Life Cycle**
- **Extended Product-Change Notification**
- **Product Traceability**



NC – No internal connection



Cross-Section View Showing PowerPAD™ Option (DGN)



(1) Additional temperature ranges are available - contact factory

RELATED DEVICES

DEVICE	DESCRIPTION
THS4051/2	70-MHz High-Speed Amplifiers
THS4081/2	175-MHz Low Power High-Speed Amplifiers



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

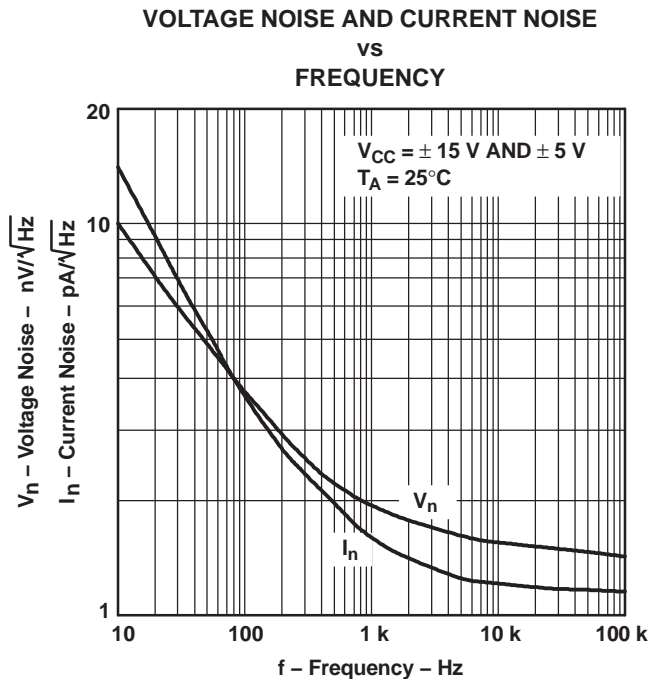
PowerPAD is a trademark of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION

The THS4031 and THS4032 are ultralow-voltage noise, high-speed voltage feedback amplifiers that are ideal for applications requiring low voltage noise, including communications and imaging. The single amplifier THS4031 and the dual amplifier THS4032 offer very good ac performance with 100-MHz bandwidth ($G = 2$), 100-V/ μ s slew rate, and 60-ns settling time (0.1%). The THS4031 and THS4032 are unity gain stable with 275-MHz bandwidth. These amplifiers have a high drive capability of 90 mA and draw only 8.5-mA supply current per channel. With -90 dBc of total harmonic distortion (THD) at $f = 1$ MHz and a very low noise of 1.6 nV/ $\sqrt{\text{Hz}}$, the THS4031 and THS4032 are ideally suited for applications requiring low distortion and low noise such as buffering analog-to-digital converters.



ORDERING INFORMATION⁽¹⁾

T_A	PACKAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	MSOP-PowerPAD	THS4032MDGNREP	NXX

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
 (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

FUNCTIONAL BLOCK DIAGRAMS

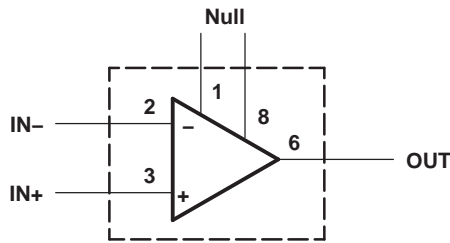


Figure 1. THS4031 – Single Channel

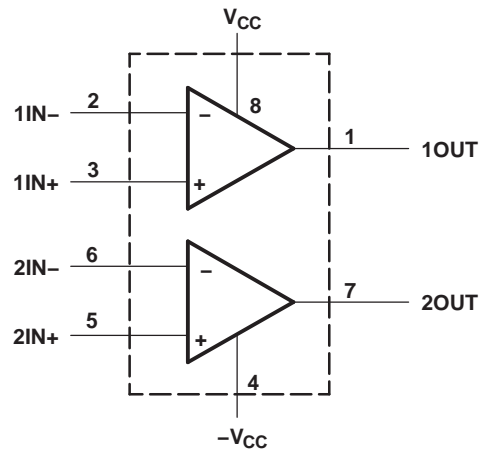


Figure 2. THS4032 – Dual Channel

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range (unless otherwise noted).

		VALUE	UNIT
V_{CC}	Supply voltage, V_{CC+} to V_{CC-}	33	V
V_I	Input voltage	$\pm V_{CC}$	
I_O	Output current	150	mA
V_{IO}	Differential input voltage	± 4	V
	Continuous total power dissipation	See Dissipation Ratings Table	
T_A	Operating free-air temperature	-55 to 125	°C
T_J	Maximum junction temperature, (any condition)	150	°C
	Maximum junction temperature, continuous operation, long term reliability ⁽²⁾	130	°C
T_{stg}	Storage temperature ⁽³⁾	-65 to 150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds, JG package	300	°C
	Case temperature for 60 seconds, FK package	260	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device. Does not apply to the JG package or FK package.
- (3) Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

DISSIPATION RATINGS TABLE

PACKAGE	θ_{JA} (°C/W)	θ_{JC} (°C/W)	$T_A = 25^\circ\text{C}$ POWER RATING
D	167 ⁽¹⁾	38.3	629 mW, $T_J = 130^\circ\text{C}$, continuous
DGN ⁽²⁾	58.4	4.7	1.8 W, $T_J = 130^\circ\text{C}$, continuous
JG	119	28	1050 mW, $T_J = 150^\circ\text{C}$, continuous
FK	87.7	20	1375 mW, $T_J = 150^\circ\text{C}$, continuous

- (1) This data was taken using the JEDEC standard Low-K test PCB. For the JEDEC Proposed High-K test PCB, the θ_{JA} is 95°C/W with a power rating at $T_A = 25^\circ\text{C}$ of 1.32 W.
- (2) This data was taken using 2 oz. trace and copper pad that is soldered directly to a 3-in x 3-in PCB. For further information, refer to *Application Information* section of this data sheet.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V _{CC+} and V _{CC-}	Supply voltage	Dual supply		V
		Single supply		
T _A	Operating free-air temperature	-55	125	°C

ELECTRICAL CHARACTERISTICS

At T_A = full range, V_{CC} = ±15 V, and R_L = 1 kΩ (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
DYNAMIC PERFORMANCE								
BW	Small-signal bandwidth (-3 dB)	V _{CC} = ±15 V		Gain = -1 or 2	100		MHz	
		V _{CC} = ±5 V			90			
	Bandwidth for 0.1-dB flatness	V _{CC} = ±15 V		Gain = -1 or 2	50		MHz	
		V _{CC} = ±5 V			45			
Full power bandwidth ⁽¹⁾	V _{O(pp)} = 20 V, V _{CC} = ±15 V		R _L = 1 kΩ	2.3		MHz		
	V _{O(pp)} = 5 V, V _{CC} = ±5 V			7.1				
SR	Slew rate ⁽²⁾	V _{CC} = ±15 V		R _L = 1 kΩ	100		V/μs	
t _s	Settling time to 0.1%	V _{CC} = ±15 V, 5-V step		Gain = -1	60		ns	
		V _{CC} = ±5 V, 2.5-V step			45			
	Settling time to 0.01%	V _{CC} = ±15 V, 5-V step		Gain = -1	90		ns	
		V _{CC} = ±5 V, 2.5-V step			80			
NOISE/DISTORTION PERFORMANCE								
THD	Total harmonic distortion	V _{CC} = ±5 V or ±15 V, V _{O(pp)} = 2 V, f = 1 MHz, Gain = 2, T _A = 25°C		R _L = 150 Ω	-81		dBc	
				R _L = 1 kΩ	-96			
V _n	Input voltage noise	V _{CC} = ±5 V or ±15 V, T _A = 25°C		f > 10 kHz	R _L = 150 Ω	1.6		nA/√Hz
I _n	Input current noise	V _{CC} = ±5 V or ±15 V, T _A = 25°C		f > 10 kHz	R _L = 150 Ω	1.2		pA/√Hz
Differential gain error		Gain = 2, 40 IRE modulation, T _A = 25°C	NTSC and PAL, ±100 IRE ramp, R _L = 150 Ω	V _{CC} = ±15 V	0.015%		°	
Differential phase error				V _{CC} = ±5 V	0.02%			
				V _{CC} = ±15 V	0.025			
				V _{CC} = ±5 V	0.03			
DC PERFORMANCE								
Open loop gain		V _{CC} = ±15 V, R _L = 1 kΩ, V _O = ±10 V		T _A = 25°C	93 98		dB	
				T _A = full range	92			
		V _{CC} = ±5 V, R _L = 1 kΩ, V _O = ±2.5 V		T _A = 25°C	92 95			
				T _A = full range	91			
V _{IO}	Input offset voltage	V _{CC} = ±5 V or ±15 V		T _A = 25°C	0.5 2		mV	
				T _A = full range	3			
I _{IB}	Input bias current	V _{CC} = ±5 V or ±15 V		T _A = 25°C	3 6		μA	
				T _A = full range	8			
I _{IO}	Input offset current	V _{CC} = ±5 V or ±15 V		T _A = 25°C	30 250		nA	
				T _A = full range	450			
Offset voltage drift		V _{CC} = ±5 V or ±15 V		T _A = full range		2		μV/°C
Input offset current drift		V _{CC} = ±5 V or ±15 V		T _A = full range		0.2		nA/°C

(1) Full power bandwidth = slew rate / [√2 πV_{OC(Peak)}].

(2) Slew rate is measured from an output level range of 25% to 75%.

ELECTRICAL CHARACTERISTICS (continued)

 At T_A = full range, $V_{CC} = \pm 15$ V, and $R_L = 1$ k Ω (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
INPUT CHARACTERISTICS							
V_{ICR}	Common-mode input voltage range	$V_{CC} = \pm 15$ V		± 13.5	± 14.3		V
		$V_{CC} = \pm 5$ V		± 3.6	± 4.3		
CMRR	Common-mode rejection ratio	$V_{CC} = \pm 15$ V, $V_{ICR} = \pm 12$ V	$T_A = 25^\circ\text{C}$	85	95		dB
			$T_A = \text{full range}$	80			
		$V_{CC} = \pm 5$ V, $V_{ICR} = \pm 2.5$ V	$T_A = 25^\circ\text{C}$	90	100		
			$T_A = \text{full range}$	85			
r_i	Input resistance				2		M Ω
C_i	Input capacitance				1.5		pF
OUTPUT CHARACTERISTICS							
V_O	Output voltage swing	$V_{CC} = \pm 15$ V	$R_L = 1$ k Ω	± 13	± 13.6		V
		$V_{CC} = \pm 5$ V		± 3.4	± 3.8		
		$V_{CC} = \pm 15$ V	$R_L = 150$ Ω	± 12	± 12.9		
		$V_{CC} = \pm 5$ V	$R_L = 250$ Ω	± 3	± 3.5		
I_O	Output current ⁽³⁾	$V_{CC} = \pm 15$ V	$R_L = 20$ Ω	60	90		mA
		$V_{CC} = \pm 5$ V		50	70		
I_{SC}	Short-circuit current ⁽³⁾	$V_{CC} = \pm 15$ V			150		mA
R_O	Output resistance	Open loop			13		Ω
POWER SUPPLY							
V_{CC}	Supply voltage operating range	Dual supply		± 4.5		± 16.5	V
		Single supply		9		33	
I_{CC}	Supply current (each amplifier)	$V_{CC} = \pm 15$ V	$T_A = 25^\circ\text{C}$		8.5	10	mA
			$T_A = \text{full range}$			11	
		$V_{CC} = \pm 5$ V	$T_A = 25^\circ\text{C}$		7.5	9	
			$T_A = \text{full range}$			10	
PSRR	Power-supply rejection ratio	$V_{CC} = \pm 5$ V or ± 15 V		$T_A = 25^\circ\text{C}$	85	95	dB
				$T_A = \text{full range}$	80		

(3) Observe power dissipation ratings to keep the junction temperature below the absolute maximum rating when the output is heavily loaded or shorted. See the [Absolute Maximum Ratings table](#) in this data sheet for more information.

PARAMETER MEASUREMENT INFORMATION

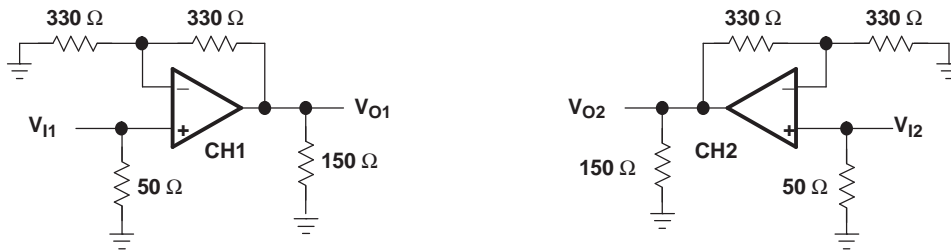


Figure 3. THS4032 Crosstalk Test Circuit

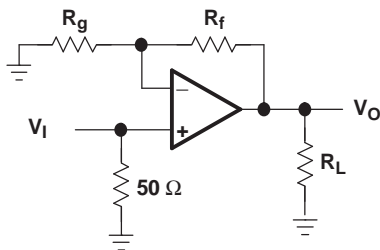


Figure 4. Step Response Test Circuit

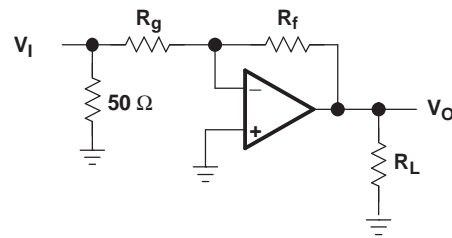


Figure 5. Step Response Test Circuit

TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
Input offset voltage distribution		6, 7
Input offset voltage	vs Free-air temperature	8
Input bias current	vs Free-air temperature	9
Output voltage swing	vs Supply voltage	10
Maximum output voltage swing	vs Free-air temperature	11
Maximum output current	vs Free-air temperature	12
Supply current	vs Free-air temperature	13
Common-mode input voltage	vs Supply voltage	14
Closed-loop output impedance	vs Frequency	15
Open-loop gain and phase response	vs Frequency	16
Power-supply rejection ratio	vs Frequency	17
Common-mode rejection ratio	vs Frequency	18
Crosstalk	vs Frequency	19
Harmonic distortion	vs Frequency	20, 21
Harmonic distortion	vs Peak-to-peak output voltage	22, 23
Slew rate	vs Free-air temperature	24
0.1% settling time	vs Output voltage step size	25
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 1k\Omega$	26
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 1k\Omega$	27
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 150k\Omega$	28
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 150k\Omega$	29
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 1k\Omega$	30
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 1k\Omega$	31
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	32
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	33
Small signal frequency response with varying feedback resistance	Gain = 2, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	34
Small signal frequency response with varying feedback resistance	Gain = 2, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	35
Small signal frequency response with varying feedback resistance	Gain = -1, $V_{CC} = \pm 15V$, $R_L = 150k\Omega$	36
Frequency response with varying output voltage swing	Gain = -1, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	37
Small signal frequency response	Gain = 5, $V_{CC} = \pm 15V$, $\pm 5V$	38
Output amplitude	vs Frequency, Gain = 2, $V_S = \pm 15V$	39
Output amplitude	vs Frequency, Gain = 2, $V_S = \pm 5V$	40
Output amplitude	vs Frequency, Gain = -1, $V_S = \pm 15V$	41
Output amplitude	vs Frequency, Gain = -1, $V_S = \pm 5V$	42
Differential phase	vs Number of 150- Ω loads	43, 44
Differential gain	vs Number of 150- Ω loads	45, 46
1-V step response	vs Time	47, 48
4-V step response	vs Time	49
20-V step response	vs Time	50

TYPICAL CHARACTERISTICS

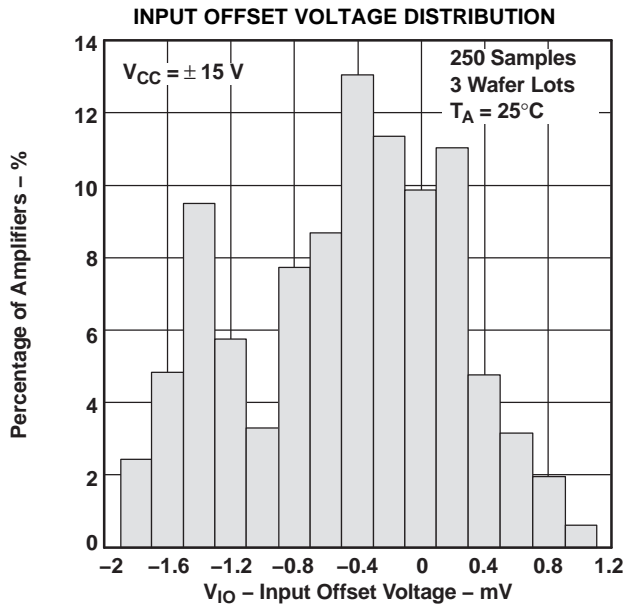


Figure 6.

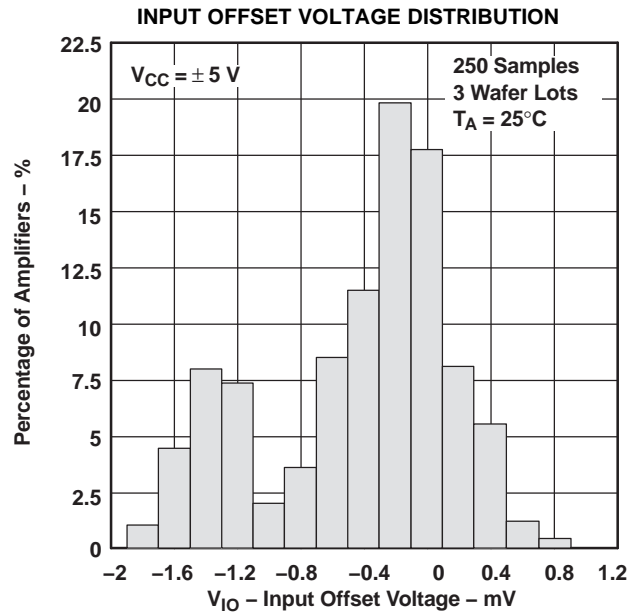


Figure 7.

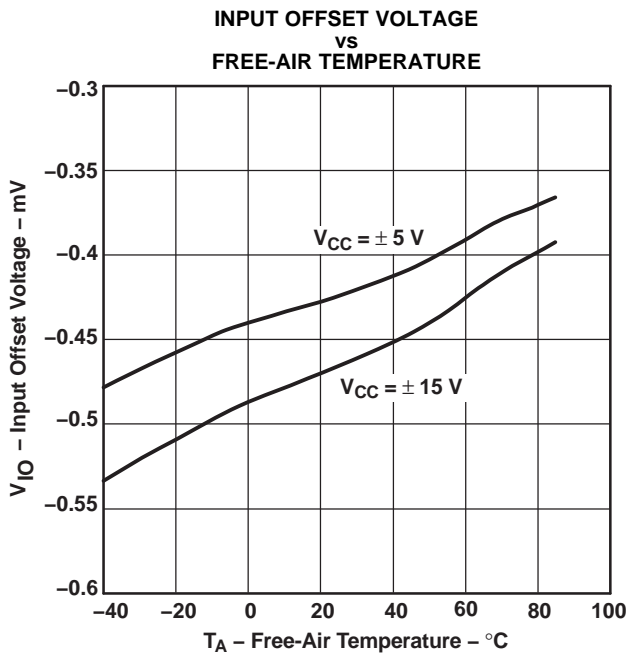


Figure 8.

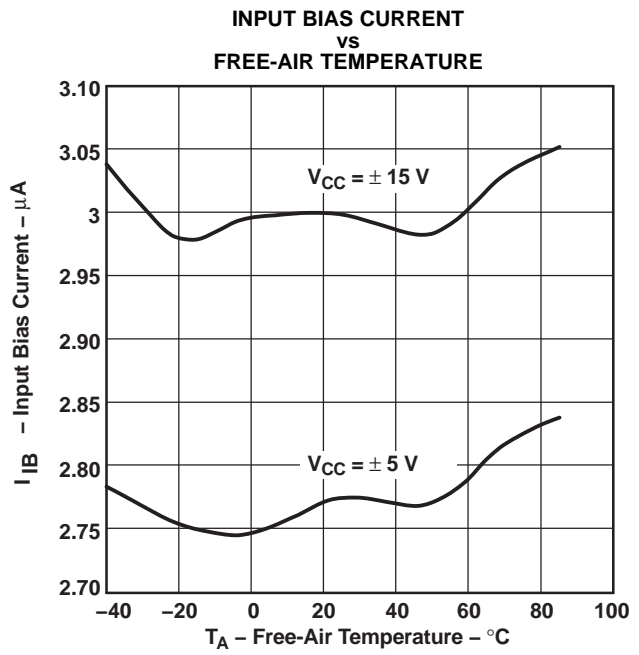


Figure 9.

TYPICAL CHARACTERISTICS (continued)

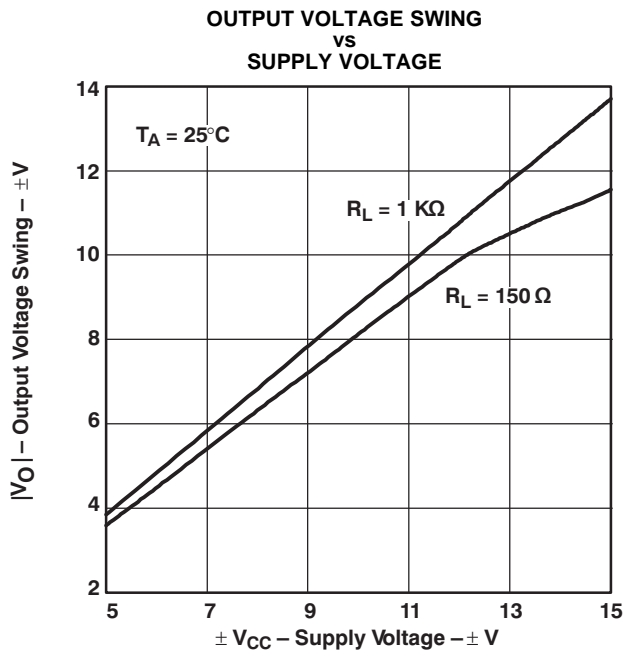


Figure 10.

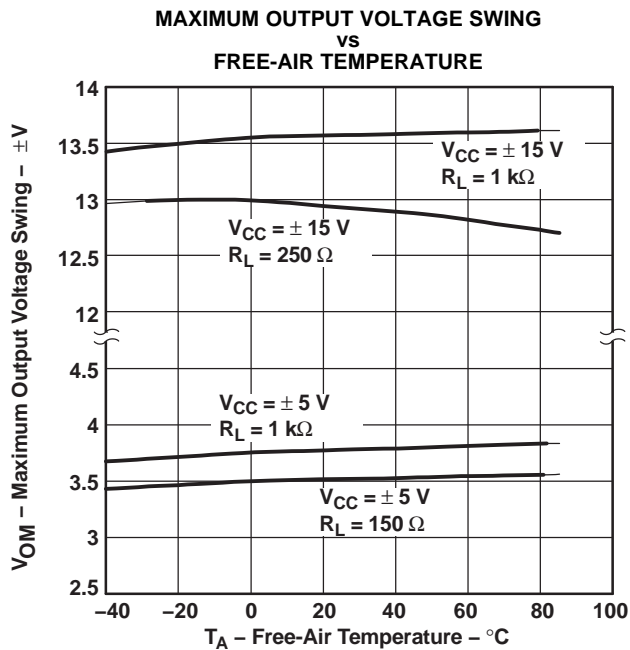


Figure 11.

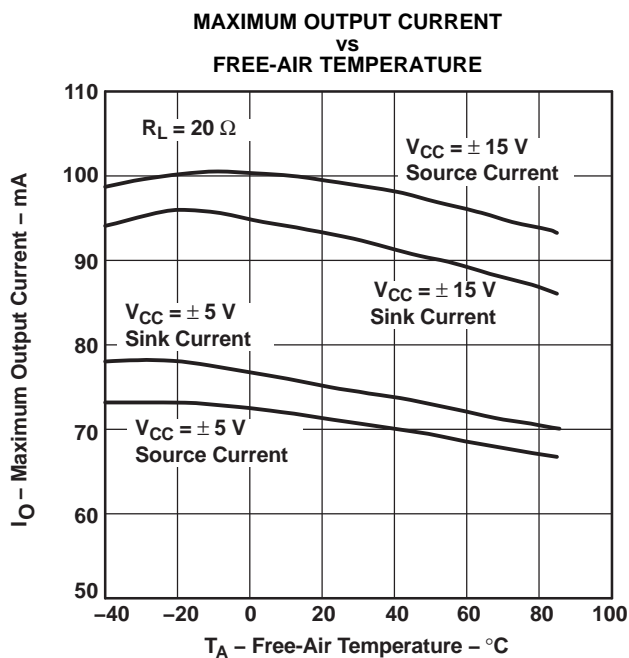


Figure 12.

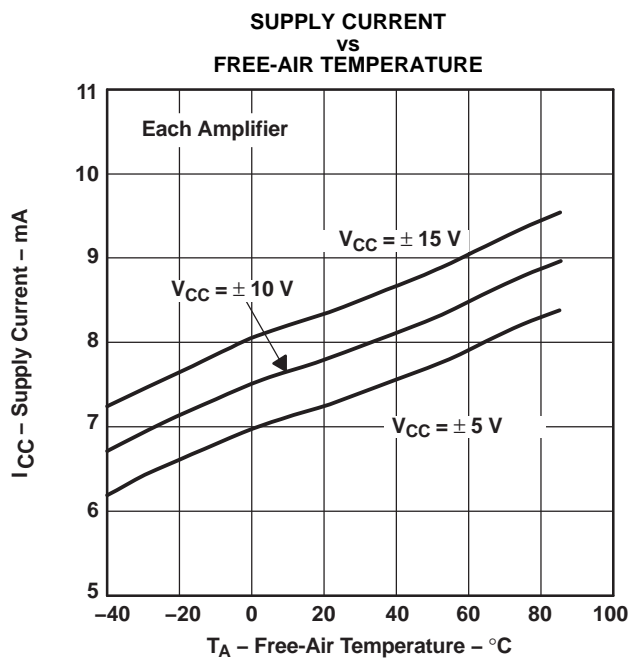


Figure 13.

TYPICAL CHARACTERISTICS (continued)

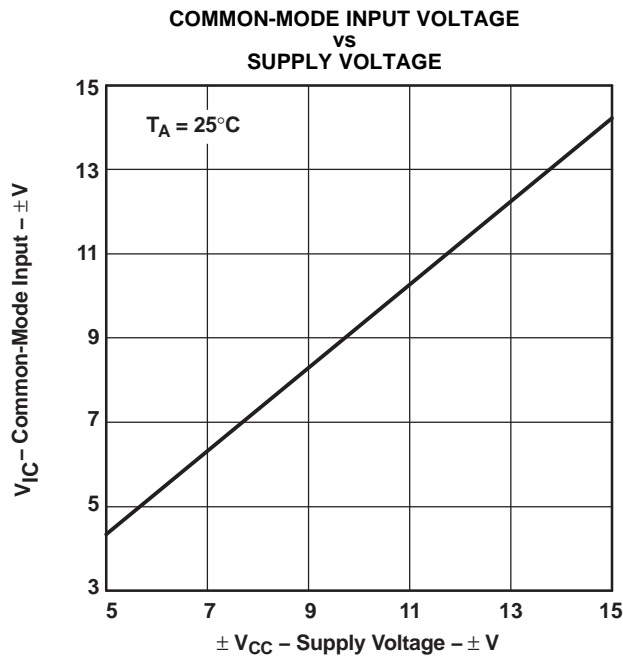


Figure 14.

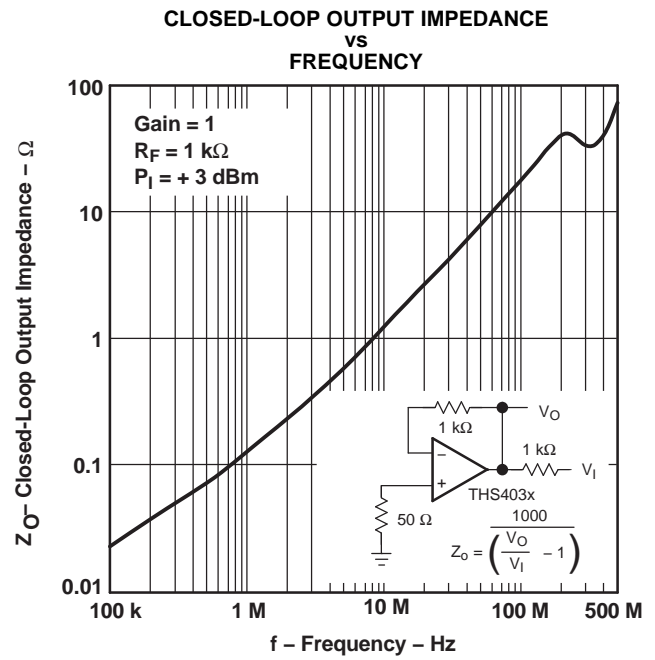


Figure 15.

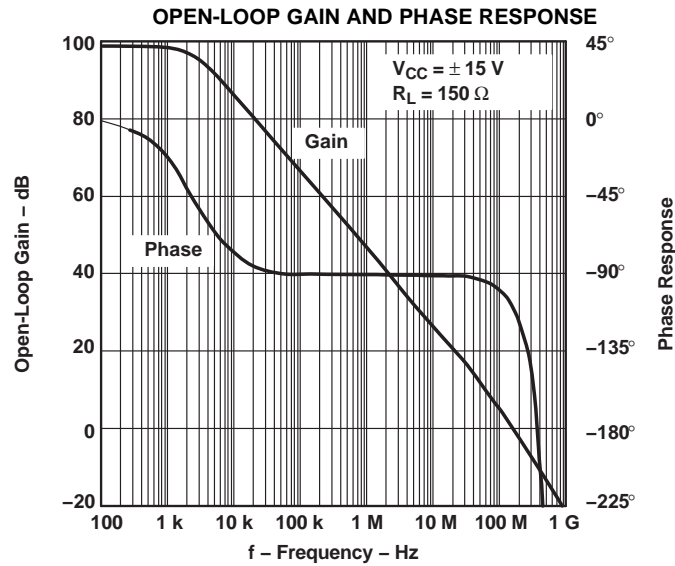


Figure 16.

TYPICAL CHARACTERISTICS (continued)

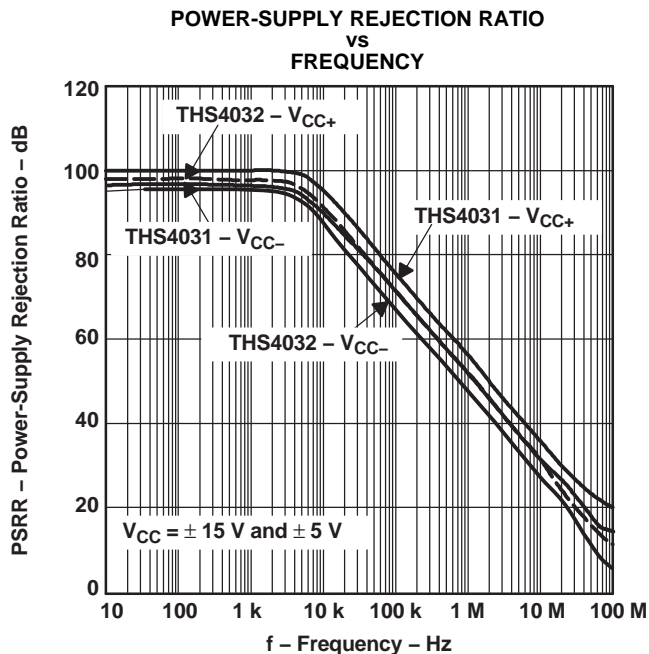


Figure 17.

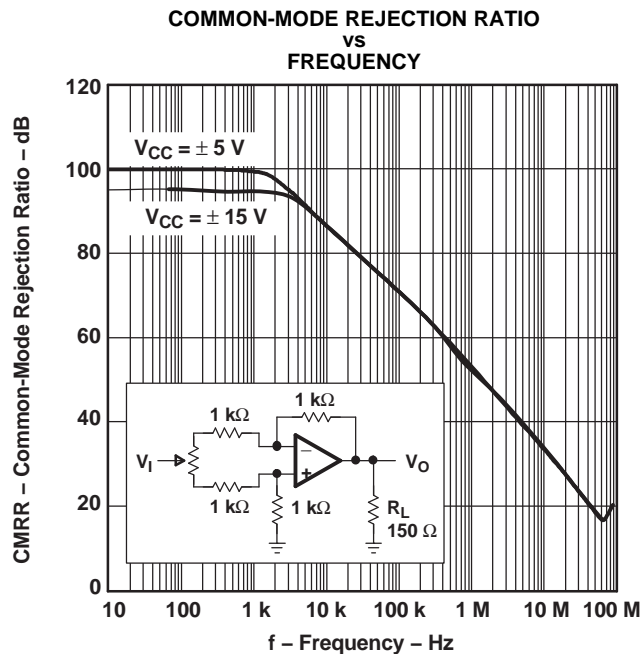


Figure 18.

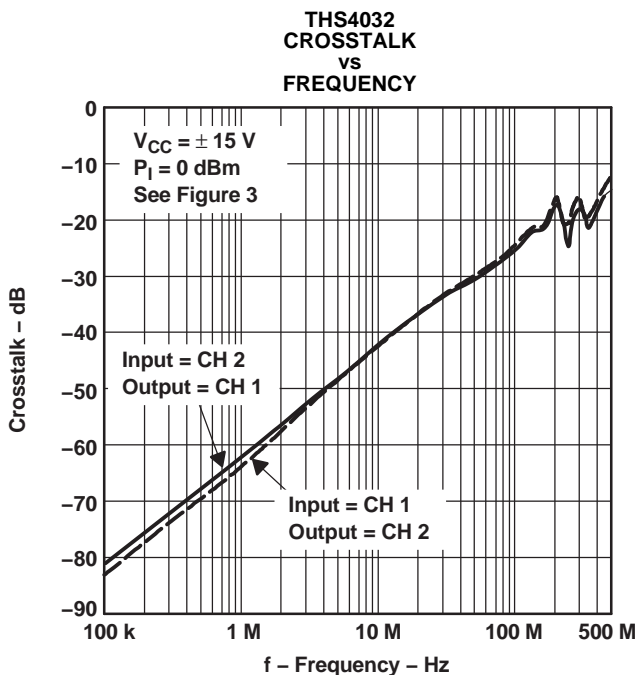


Figure 19.

TYPICAL CHARACTERISTICS (continued)

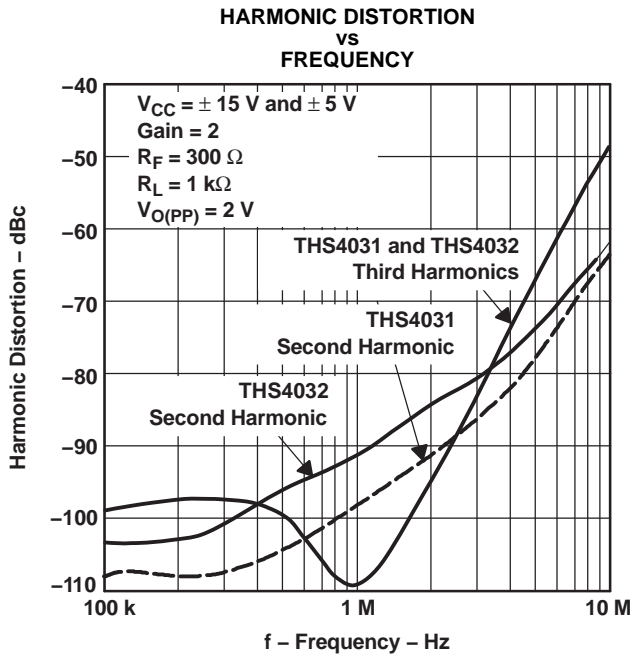


Figure 20.

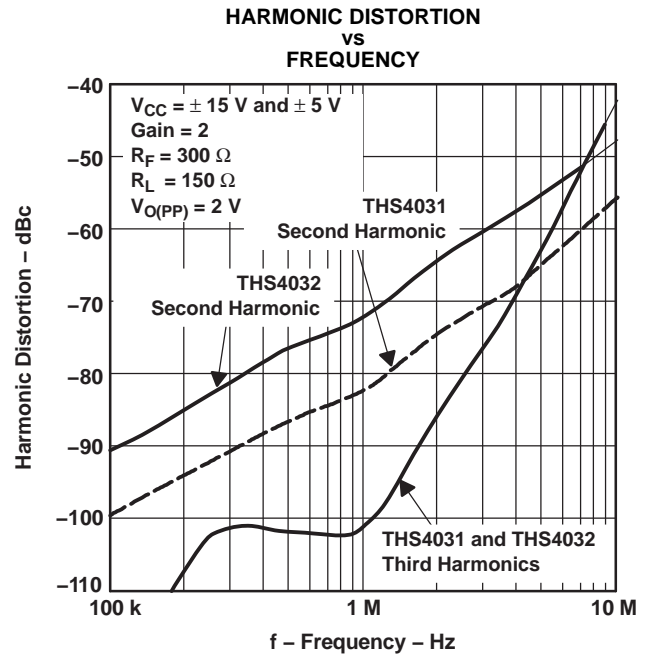


Figure 21.

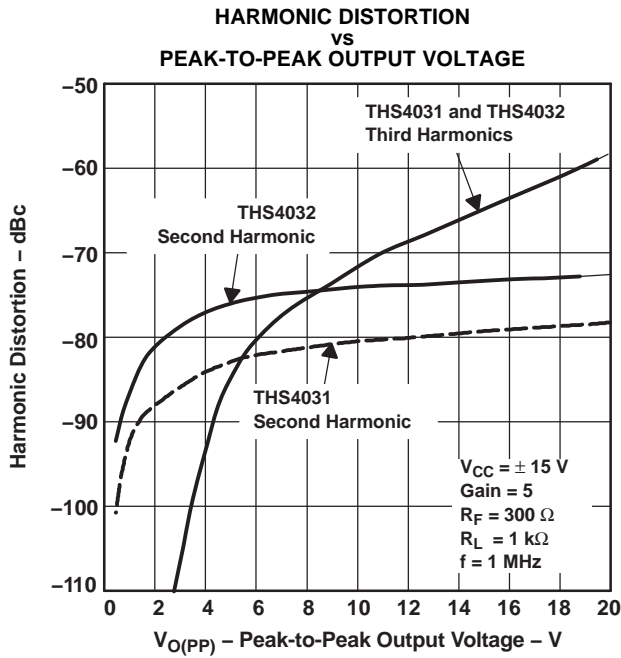


Figure 22.

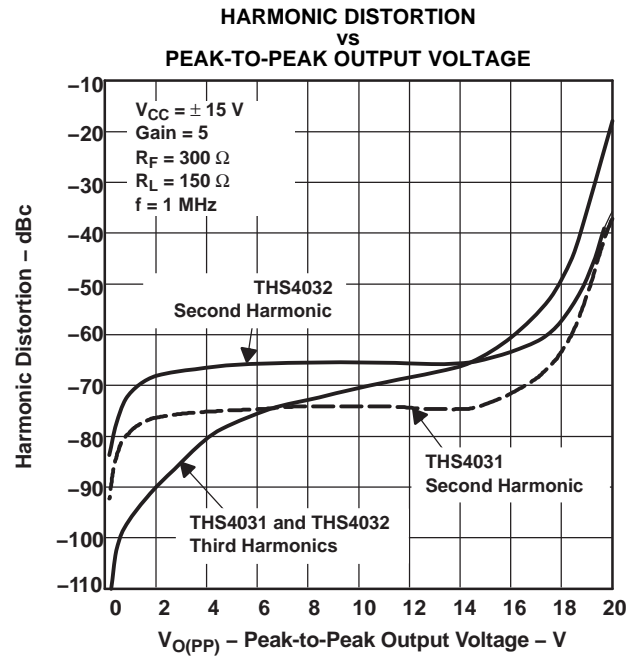


Figure 23.

TYPICAL CHARACTERISTICS (continued)

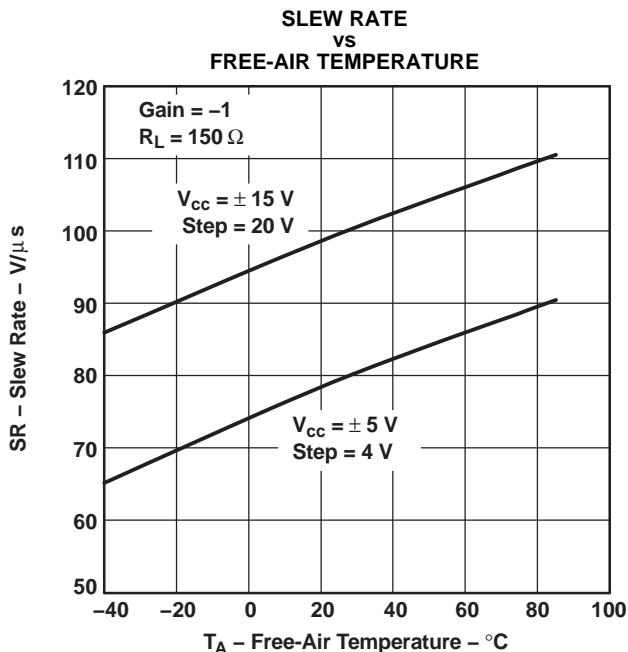


Figure 24.

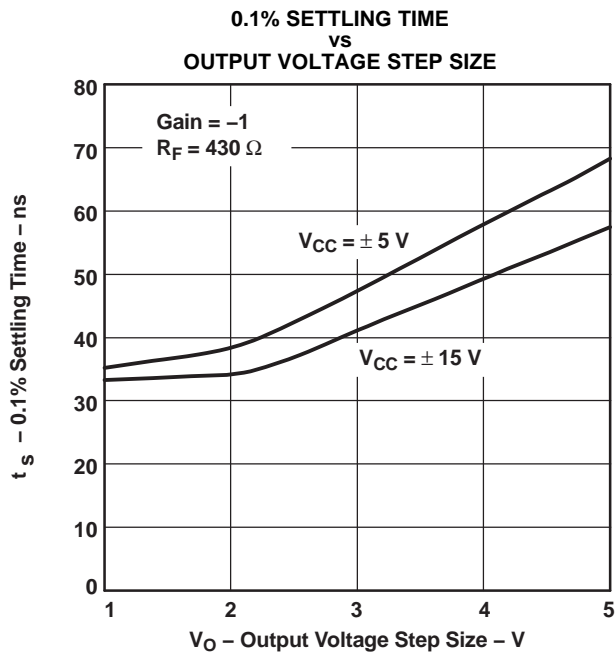


Figure 25.

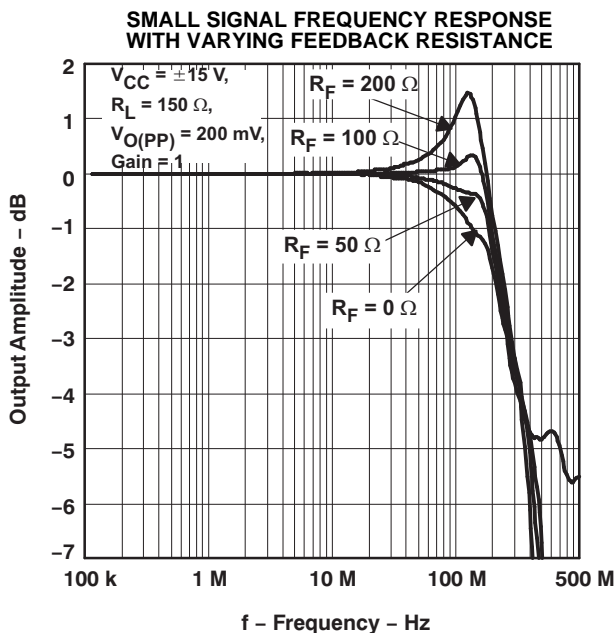


Figure 26.

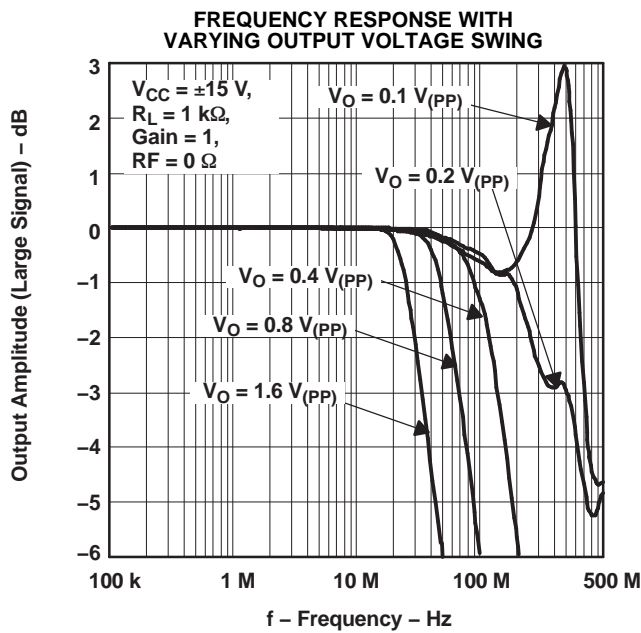


Figure 27.

TYPICAL CHARACTERISTICS (continued)

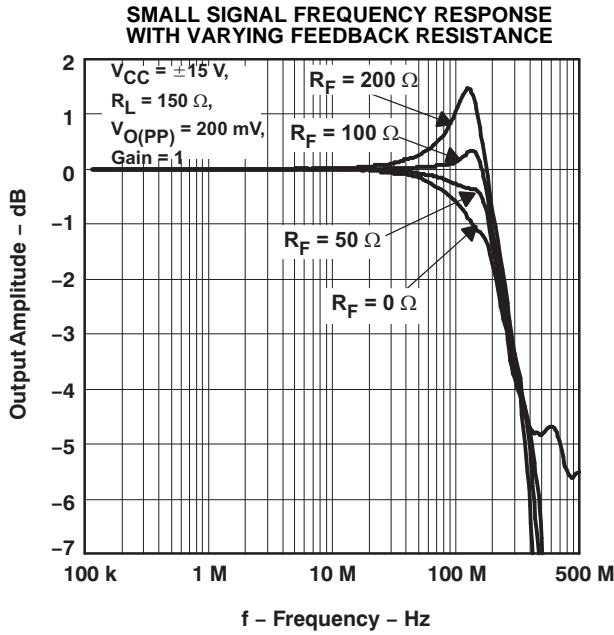


Figure 28.

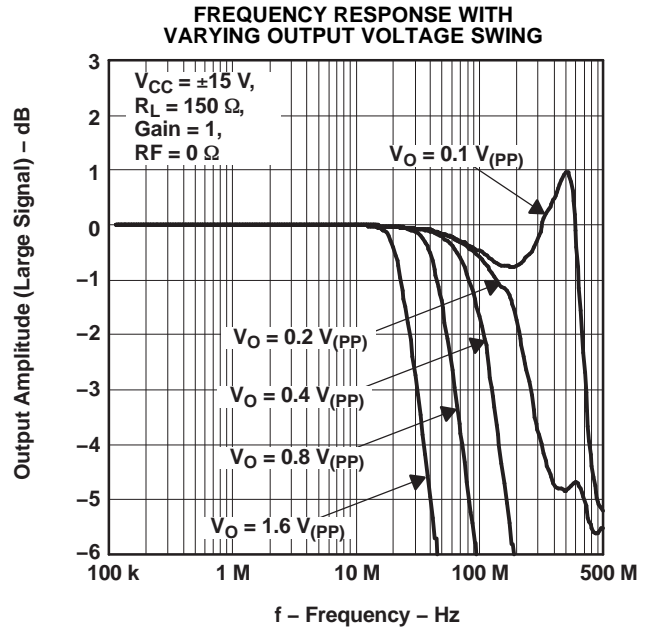


Figure 29.

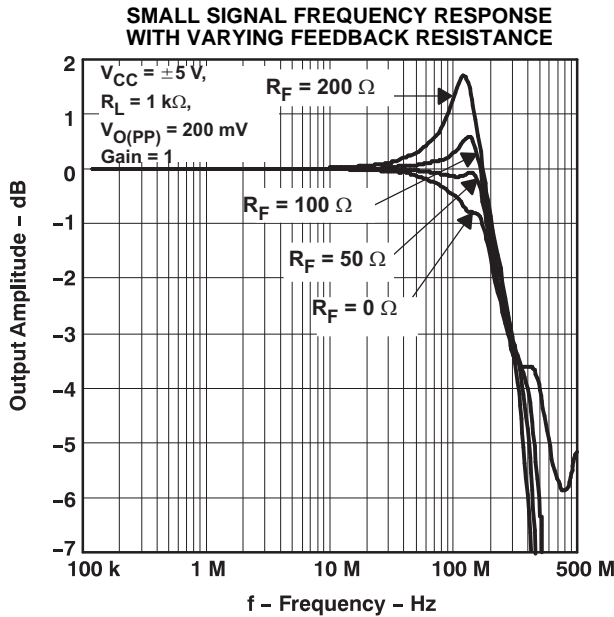


Figure 30.

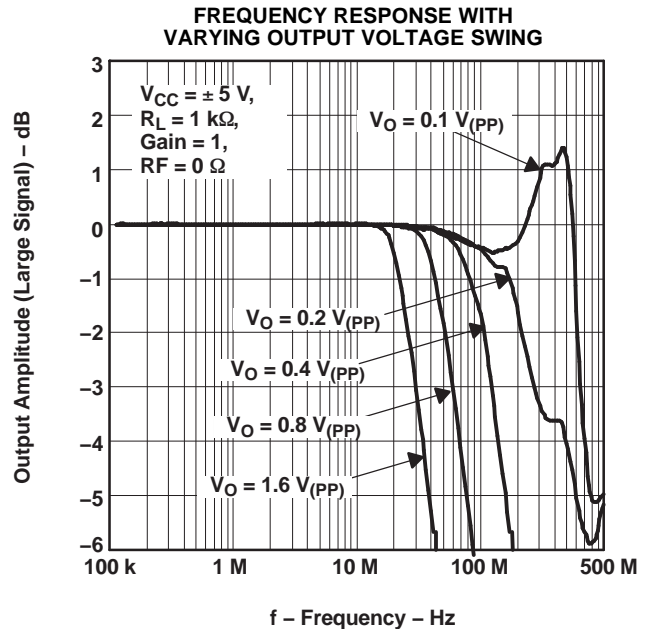


Figure 31.

TYPICAL CHARACTERISTICS (continued)

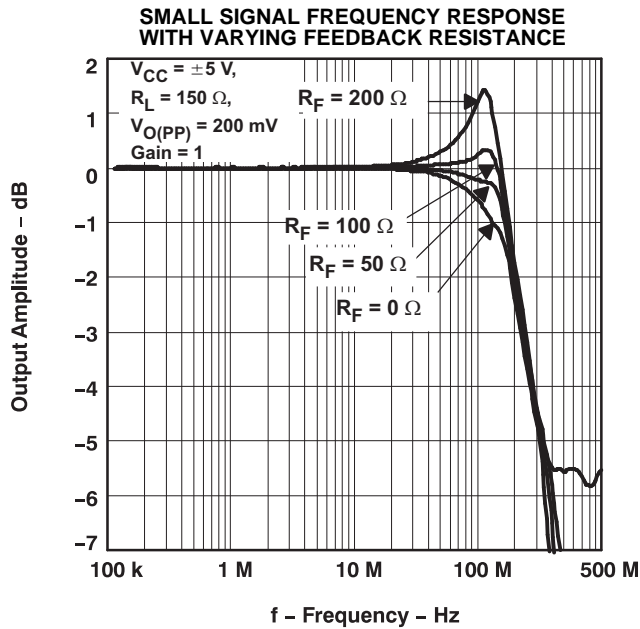


Figure 32.

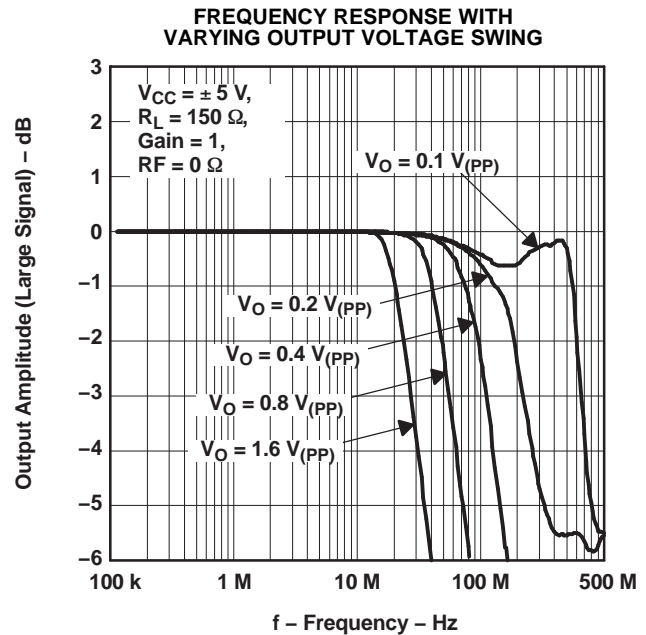


Figure 33.

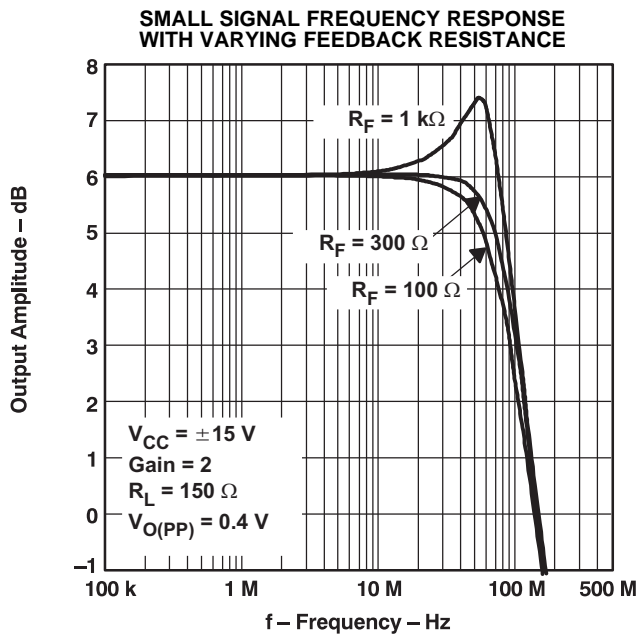


Figure 34.

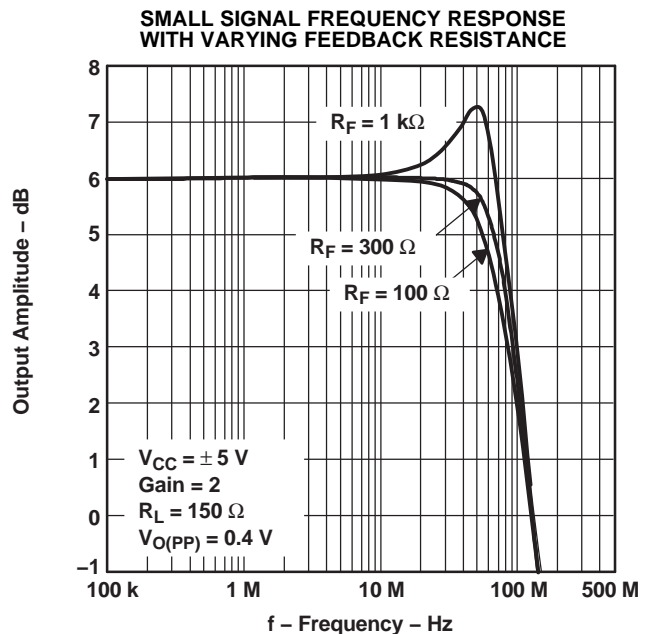


Figure 35.

TYPICAL CHARACTERISTICS (continued)

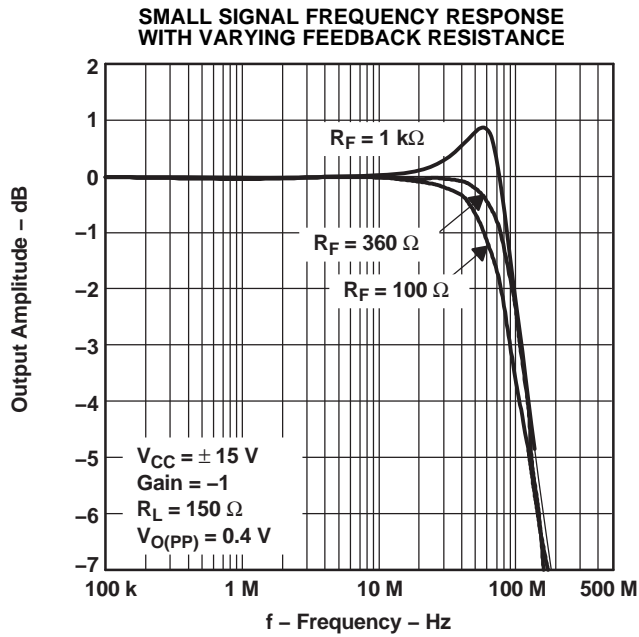


Figure 36.

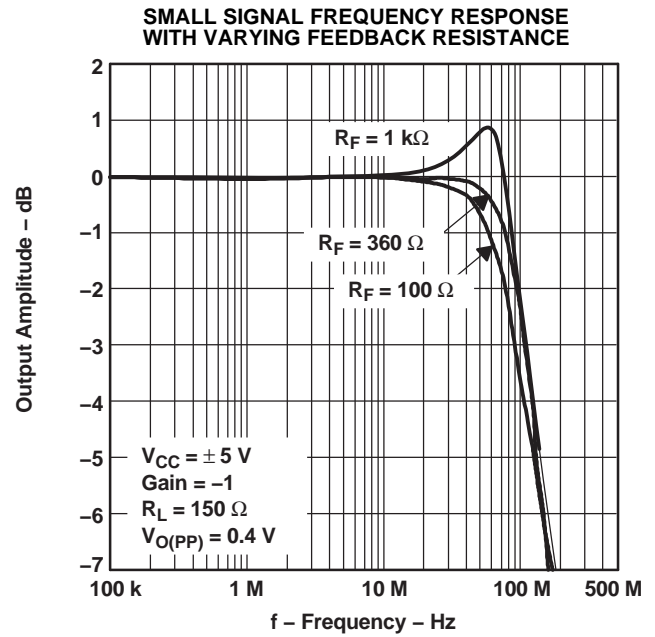


Figure 37.

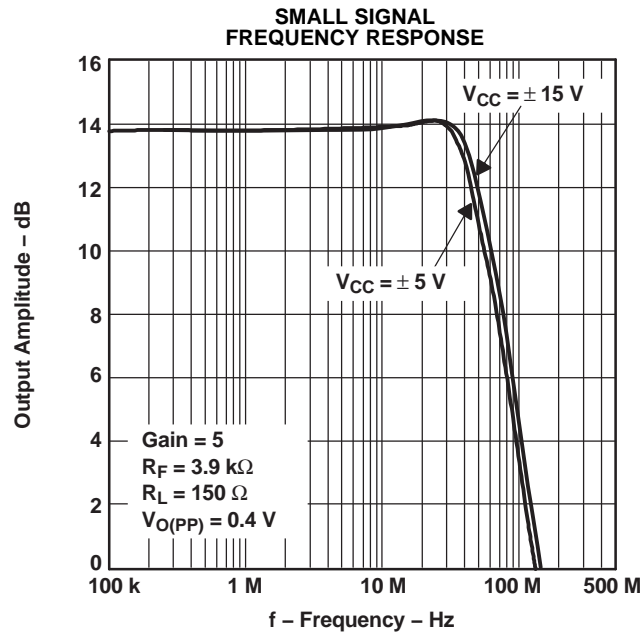


Figure 38.

TYPICAL CHARACTERISTICS (continued)

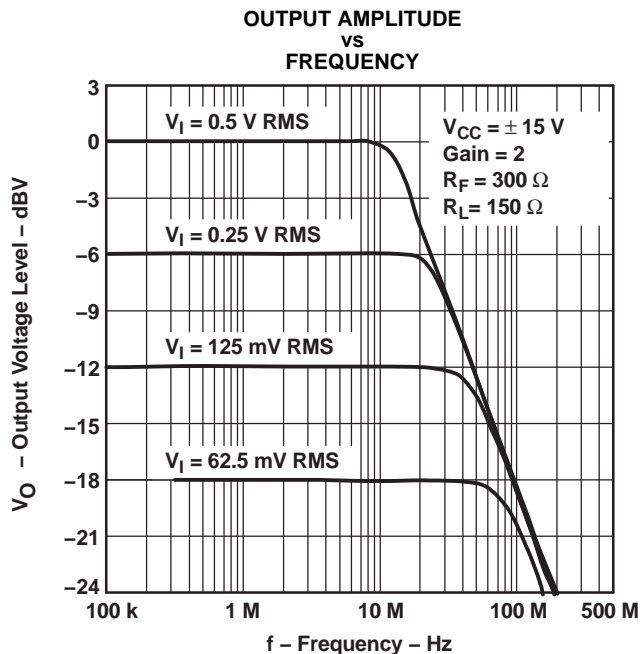


Figure 39.

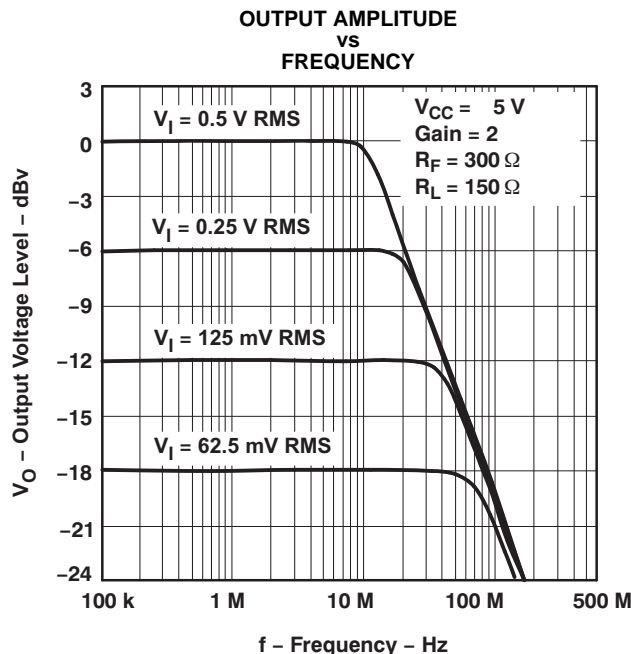


Figure 40.

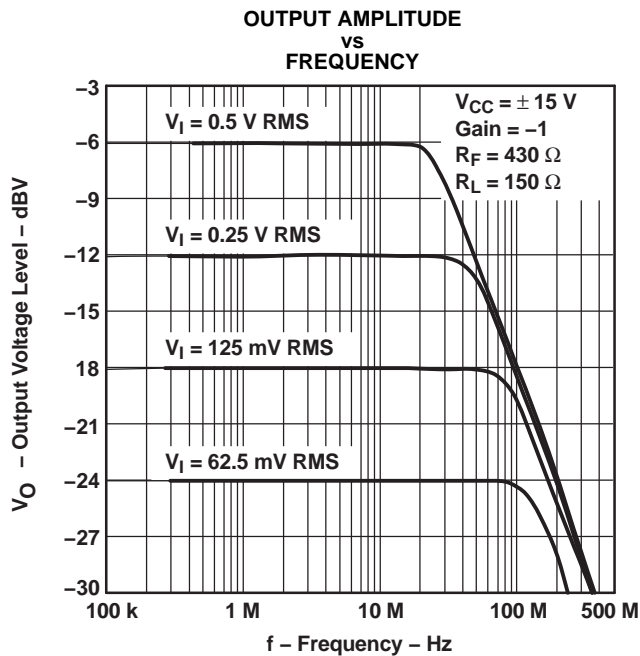


Figure 41.

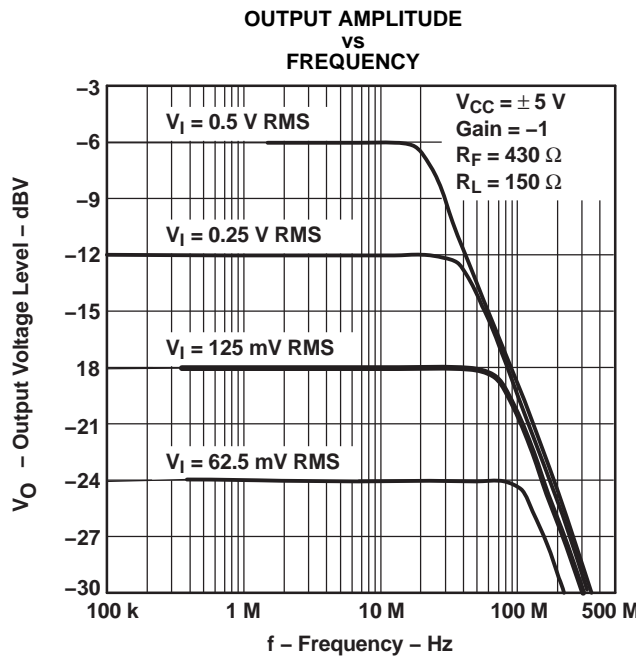
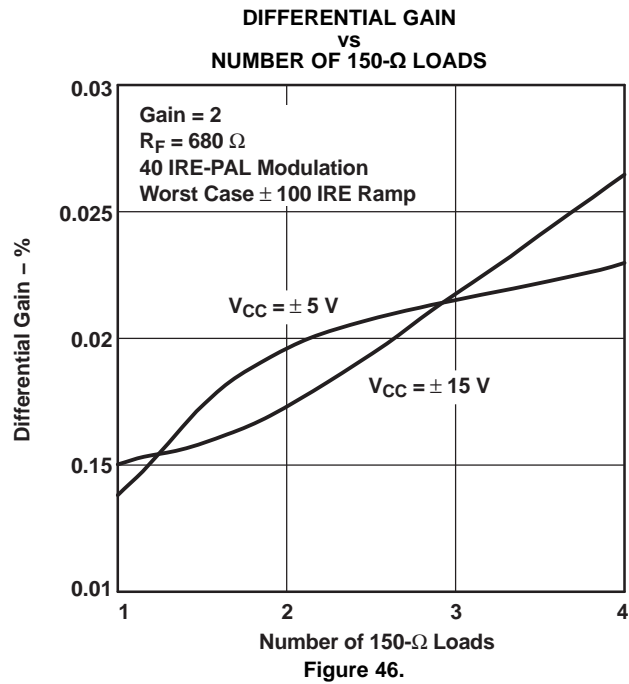
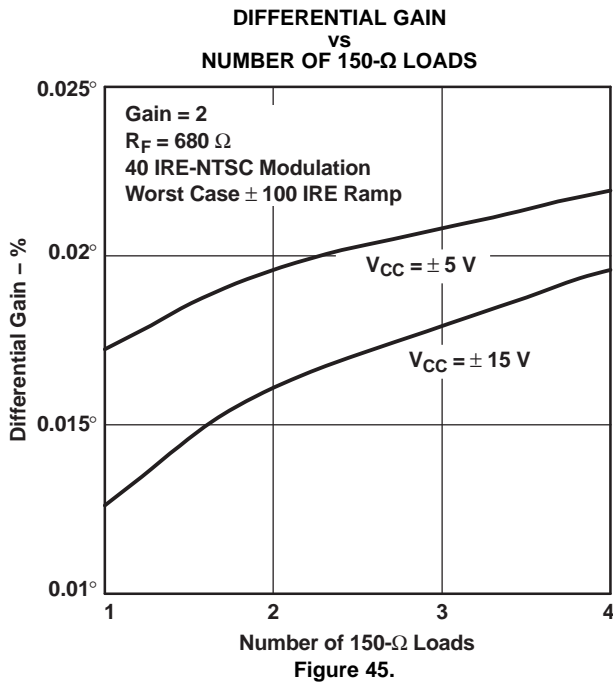
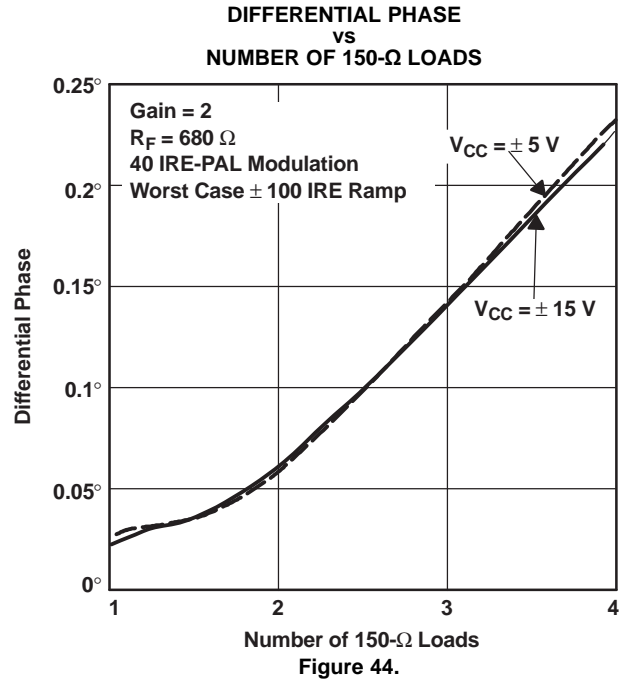
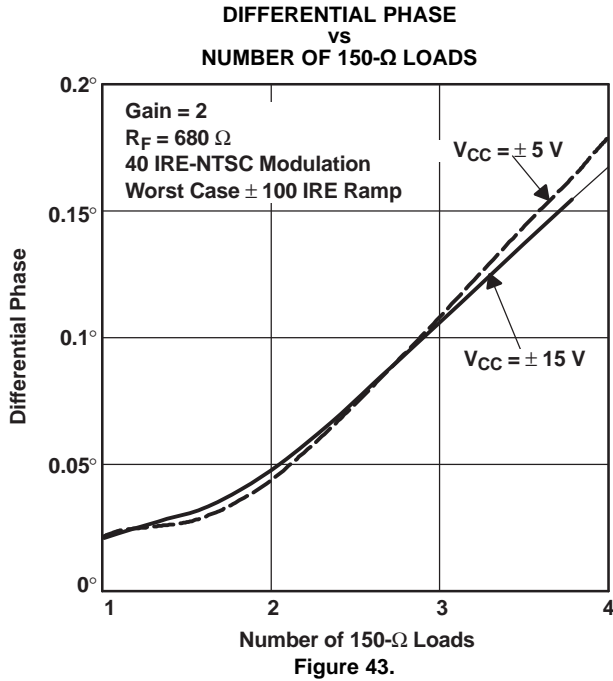
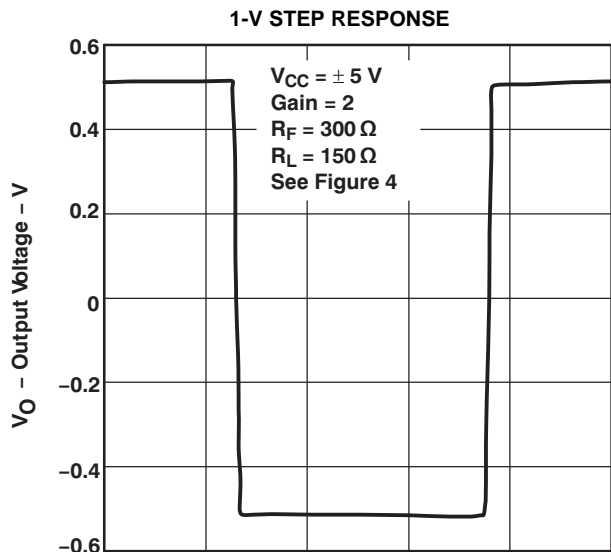


Figure 42.

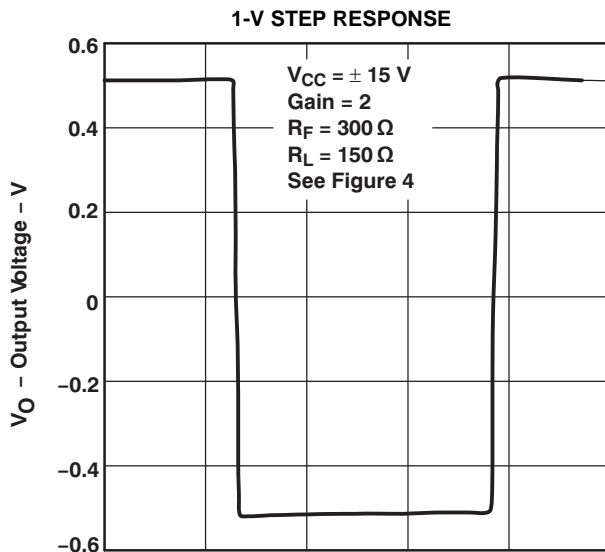
TYPICAL CHARACTERISTICS (continued)



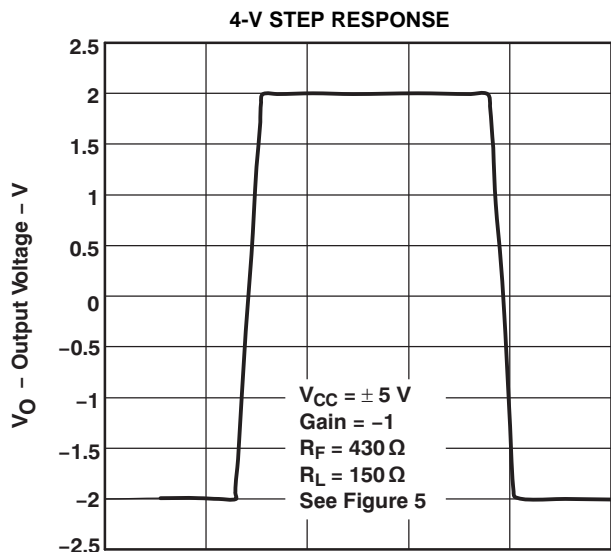
TYPICAL CHARACTERISTICS (continued)



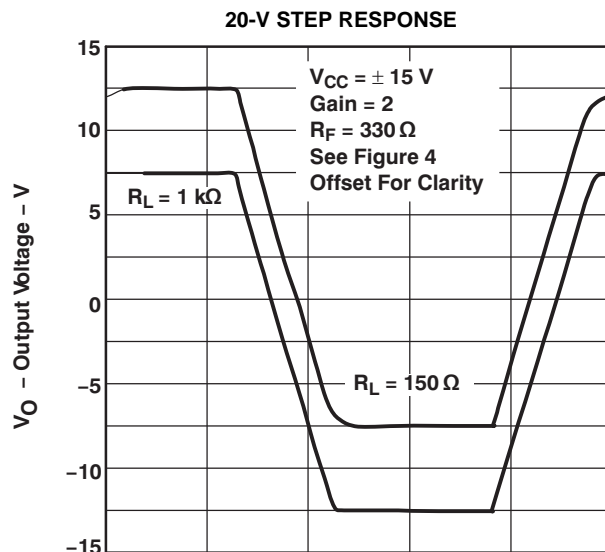
t - Time - 200 ns/div
Figure 47.



t - Time - 200 ns/div
Figure 48.



t - Time - 200 ns/div
Figure 49.



t - Time - 200 ns/div
Figure 50.

APPLICATION INFORMATION

THEORY OF OPERATION

The THS403x is a high-speed operational amplifier configured in a voltage feedback architecture. It is built using a 30-V, dielectrically isolated, complementary bipolar process with NPN and PNP transistors possessing f_T s of several GHz. This results in an exceptionally high-performance amplifier that has wide bandwidth, high slew rate, fast settling time, and low distortion. A simplified schematic is shown in [Figure 51](#).

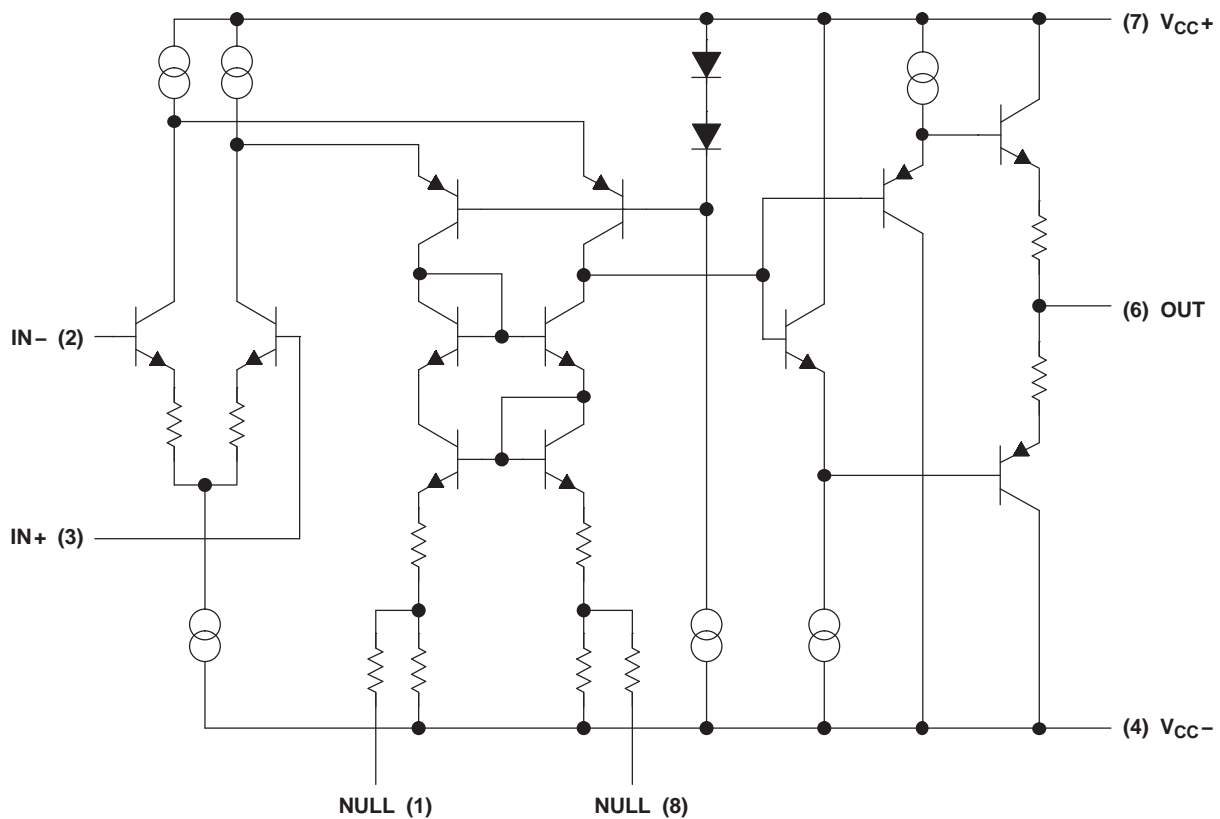


Figure 51. THS4031 Simplified Schematic

NOISE CALCULATIONS AND NOISE FIGURE

Noise can cause errors on very small signals. This is especially true when amplifying small signals. The noise model for the THS403x, shown in Figure 52, includes all of the noise sources as follows:

- e_n = Amplifier internal voltage noise ($\text{nV}/\sqrt{\text{Hz}}$)
- $\text{IN}+$ = Noninverting current noise ($\text{pA}/\sqrt{\text{Hz}}$)
- $\text{IN}-$ = Inverting current noise ($\text{pA}/\sqrt{\text{Hz}}$)
- e_{R_x} = Thermal voltage noise associated with each resistor ($e_{R_x} = 4 \text{ kTR}_x$)

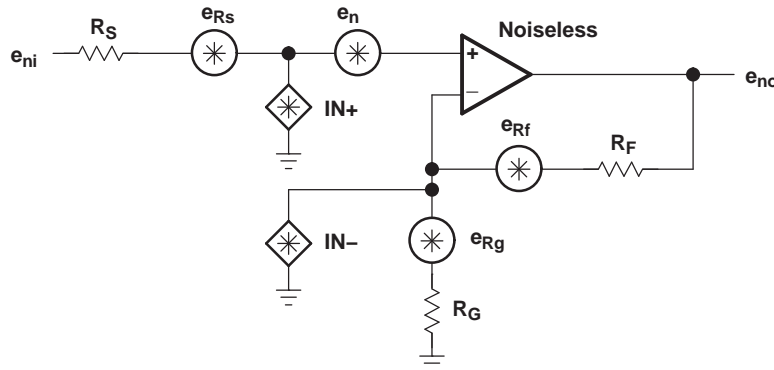


Figure 52. Noise Model

The total equivalent input noise density (e_{ni}) is calculated by using the following equation:

$$e_{ni} = \sqrt{(e_n)^2 + (\text{IN}+ \times R_S)^2 + (\text{IN}- \times (R_F \parallel R_G))^2 + 4 \text{ kTR}_S + 4 \text{ kT}(R_F \parallel R_G)}$$

Where:

k = Boltzmann's constant = 1.380658×10^{-23}

T = Temperature in degrees Kelvin ($273 + ^\circ\text{C}$)

$R_F \parallel R_G$ = Parallel resistance of R_F and R_G

(1)

To get the equivalent output noise of the amplifier, just multiply the equivalent input noise density (e_{ni}) by the overall amplifier gain (A_V).

$$e_{no} = e_{ni} A_V = e_{ni} \left(1 + \frac{R_F}{R_G} \right) \text{ (Noninverting Case)}$$

(2)

As the previous equations show, to keep noise at a minimum, small-value resistors should be used. As the closed-loop gain is increased (by reducing R_G), the input noise is reduced considerably because of the parallel resistance term. This leads to the general conclusion that the most dominant noise sources are the source resistor (R_S) and the internal amplifier noise voltage (e_n). Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be effectively ignored. This advantage can greatly simplify the formula and make noise calculations much easier to calculate.

For more information on noise analysis, refer to the application note, *Noise Analysis for High-Speed Op Amps* (SBOA066).

OPTIMIZING FREQUENCY RESPONSE

Internal frequency compensation of the THS403x was selected to provide very wide bandwidth performance and still maintain a very low noise floor. In order to meet these performance requirements, the THS403x must have a minimum gain of 2 (–1). Because everything is referred to the noninverting terminal of an operational amplifier, the noise gain in a $G = -1$ configuration is the same as a $G = 2$ configuration.

One of the keys to maintaining a smooth frequency response, and hence, a stable pulse response, is to pay particular attention to the inverting terminal. Any stray capacitance at this node causes peaking in the frequency response (see Figure 53 and Figure 54). Two things can be done to help minimize this effect. The first is to simply remove any ground planes under the inverting terminal of the amplifier, including the trace that connects to this terminal. Additionally, the length of this trace should be minimized. The capacitance at this node causes a lag in the voltage being fed back due to the charging and discharging of the stray capacitance. If this lag becomes too long, the amplifier will not be able to correctly keep the noninverting terminal voltage at the same potential as the inverting terminal's voltage. Peaking and possible oscillations will then occur if this happens.

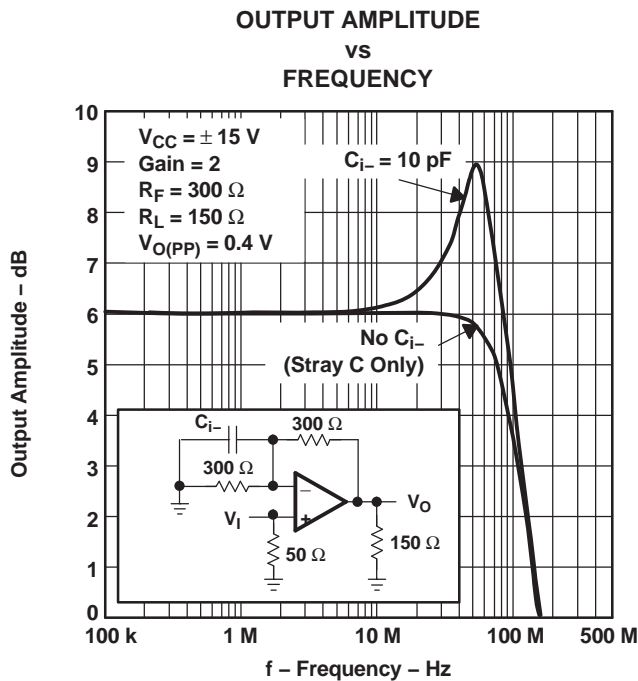


Figure 53.

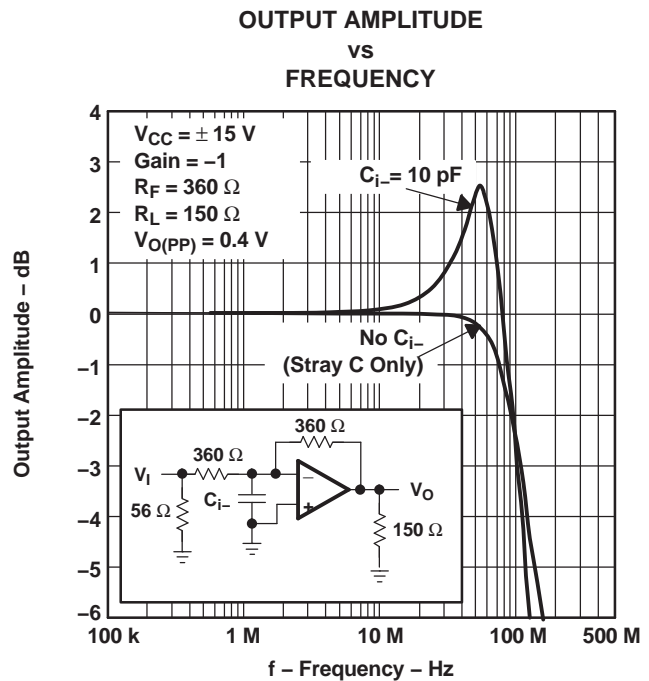


Figure 54.

The second precaution to help maintain a smooth frequency response is to keep the feedback resistor (R_f) and the gain resistor (R_g) values fairly low. These two resistors are effectively in parallel when looking at the ac small-signal response. But, as can be seen in Figure 26 through Figure 37, a value too low starts to reduce the bandwidth of the amplifier. Table 1 shows some recommended feedback resistors to be used with the THS403x.

Table 1. Recommended Feedback Resistors

GAIN	R_f for $V_{CC} = \pm 15\text{ V}$ and $\pm 5\text{ V}$
1	50 Ω
2	300 Ω
–1	360 Ω
5	3.3 k Ω (low stray-c PCB only)

DRIVING A CAPACITIVE LOAD

Driving capacitive loads with high-performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS403x has been internally compensated to maximize its bandwidth and slew-rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output will decrease the phase margin of the device leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in Figure 55. A minimum value of 20 Ω should work well for most applications. For example, in 75-Ω transmission systems, setting the series resistor value to 75 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.

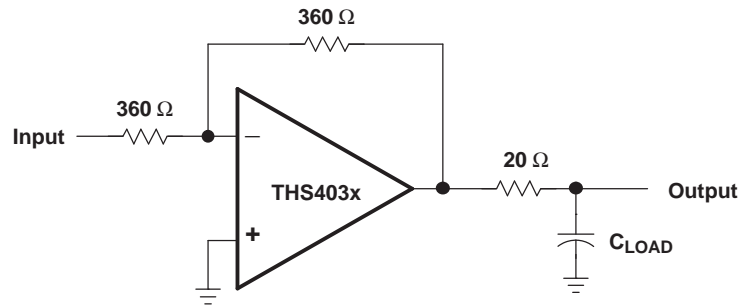


Figure 55. Driving a Capacitive Load

OFFSET NULLING

The THS403x has very low input offset voltage for a high speed amplifier. However, if additional correction is required, the designer can make use of an offset nulling function provided on the THS4031. By placing a potentiometer between terminals 1 and 8 of the device and tying the wiper to the negative supply, the input offset can be adjusted. This is shown in [Figure 56](#).

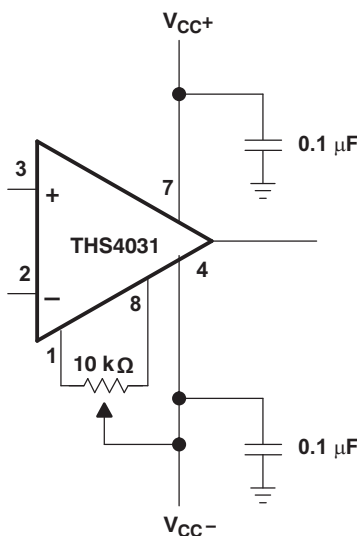


Figure 56. Offset Nulling Schematic

OFFSET VOLTAGE

The output offset voltage (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

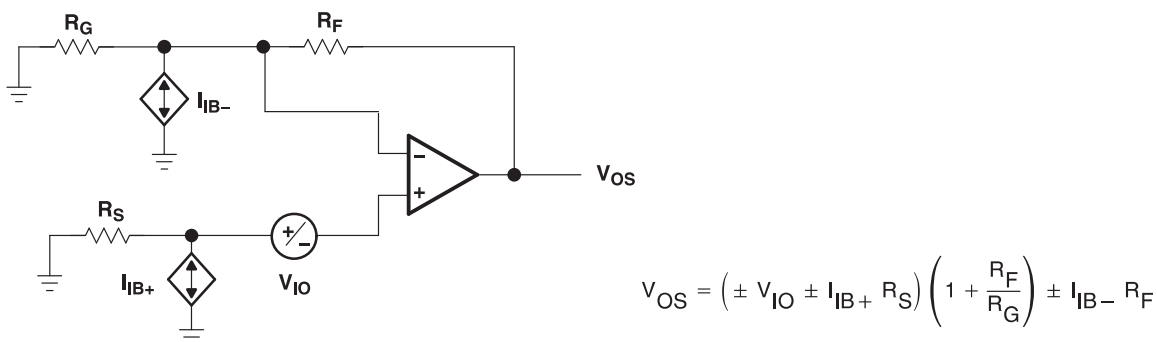


Figure 57. Output Offset Voltage Model

GENERAL CONFIGURATIONS

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 58).

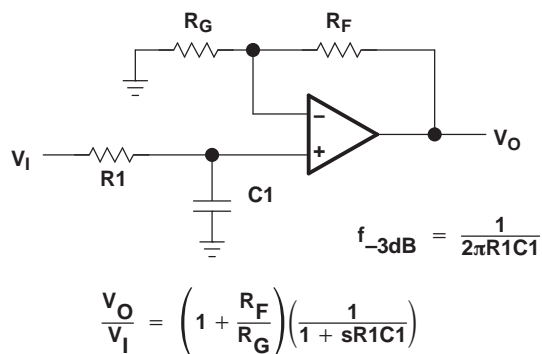


Figure 58. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple-pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Otherwise, phase shift of the amplifier can occur.

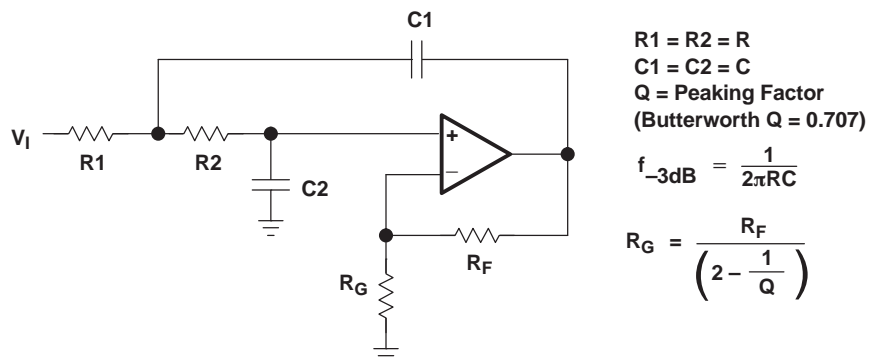


Figure 59. Two-Pole Low-Pass Sallen-Key Filter

CIRCUIT-LAYOUT CONSIDERATIONS

In order to achieve the levels of high-frequency performance of the THS403x, it is essential that proper printed-circuit board (PCB) high-frequency design techniques be followed. A general set of guidelines is given below. In addition, a THS403x evaluation board is available to use as a guide for layout or for evaluating the device performance.

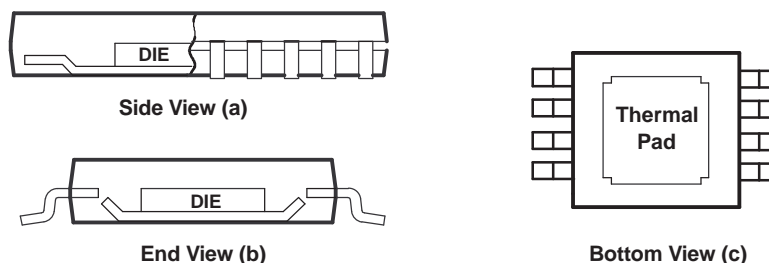
- **Ground planes:** It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- **Proper power-supply decoupling:** Use a 6.8- μF tantalum capacitor in parallel with a 0.1- μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inch between the device power terminals and the ceramic capacitors.
- **Sockets:** Sockets are not recommended for high-speed operational amplifiers. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- **Short trace runs/compact part placements:** Optimum high-frequency performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- **Surface-mount passive components:** Using surface-mount passive components is recommended for high-frequency amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

GENERAL PowerPAD™ DESIGN CONSIDERATIONS

The THS403x is available in a thermally-enhanced DGN package, which is a member of the PowerPAD family of packages. This package is constructed using a downset leadframe upon which the die is mounted [see [Figure 60\(a\)](#) and [Figure 60\(b\)](#)]. This arrangement results in the leadframe being exposed as a thermal pad on the underside of the package [see [Figure 60\(c\)](#)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat-dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the heretofore awkward mechanical methods of heatsinking.



- A. The thermal pad is electrically isolated from all terminals in the package.

Figure 60. Views of Thermally-Enhanced DGN Package

Although there are many ways to properly heatsink this device, the following steps illustrate the recommended approach.

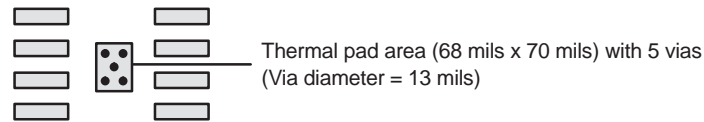


Figure 61. PowerPAD™ PCB Etch and Via Pattern

1. Prepare the PCB with a top-side etch pattern as shown in [Figure 61](#). There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes should be 13 mils (0,3302 mm) in diameter. They are kept small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS403xDGN IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, *do not* use the typical web or spoke via connection methodology. Web connections have a high thermal-resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS403xDGN package should connect to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes exposed. The bottom-side solder mask should cover the five holes of the thermal pad area, which prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and to all the IC terminals.
8. With these preparatory steps in place, the THS403xDGN IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

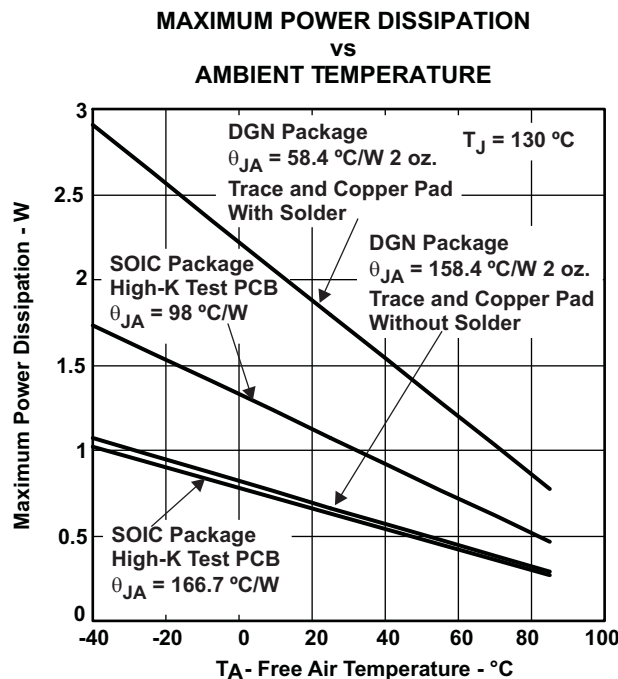
The actual thermal performance achieved with the THS403xDGN in its PowerPAD™ package depends on the application. In the example above, if the size of the internal ground plane is approximately 3 inches × 3 inches (7,62 cm × 7,62 cm), then the expected thermal coefficient, θ_{JA} , is about 58.4°C/W. For comparison, the non-PowerPAD™ version of the THS403x IC (SOIC) is shown. For a given θ_{JA} , the maximum power dissipation is shown in Figure 62 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

- P_D = Maximum power dissipation of THS403x IC (watts)
- T_{MAX} = Absolute maximum operating junction temperature (125°C)
- T_A = Free-ambient air temperature (°C)
- θ_{JA} = $\theta_{JC} + \theta_{CA}$
 - θ_{JC} = Thermal coefficient from junction to case
 - θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

(3)



Results are with no air flow and PCB size = 3" × 3" (7,62 cm × 7,62 cm)

Figure 62. Maximum Power Dissipation vs Free-Air Temperature

More complete details of the PowerPAD installation process and thermal management techniques can be found in the Texas Instruments technical brief, *PowerPAD™ Thermally-Enhanced Package (SLMA002)*. This document can be found at the TI web site (www.ti.com) by searching on the key word PowerPAD. The document can also be ordered through your local TI sales office. Refer to literature number [SLMA002](#) when ordering.

The next thing to be considered is package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents. Figure 63 to Figure 66 shows this effect, along with the quiescent heat, with an ambient air temperature of 50°C. When using $V_{CC} = \pm 5$ V, heat is generally not a problem, even with SOIC packages. But, when using $V_{CC} = \pm 15$ V, the SOIC package is severely limited in the amount of heat it can dissipate. The other key factor when looking at these graphs is how the devices are mounted on the PCB. The PowerPAD™ devices are extremely useful for heat dissipation. But, the device should

always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD™. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual amplifier package (THS4032), the sum of the RMS output currents and voltages should be used to choose the proper package.

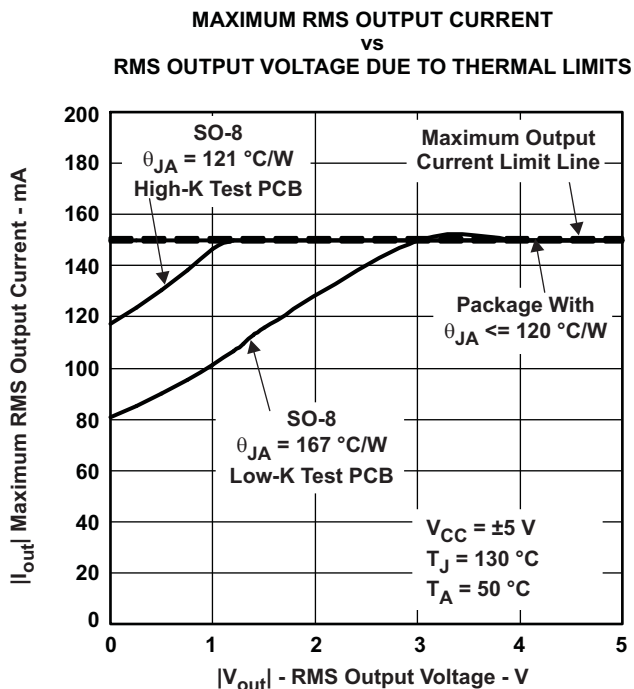


Figure 63.

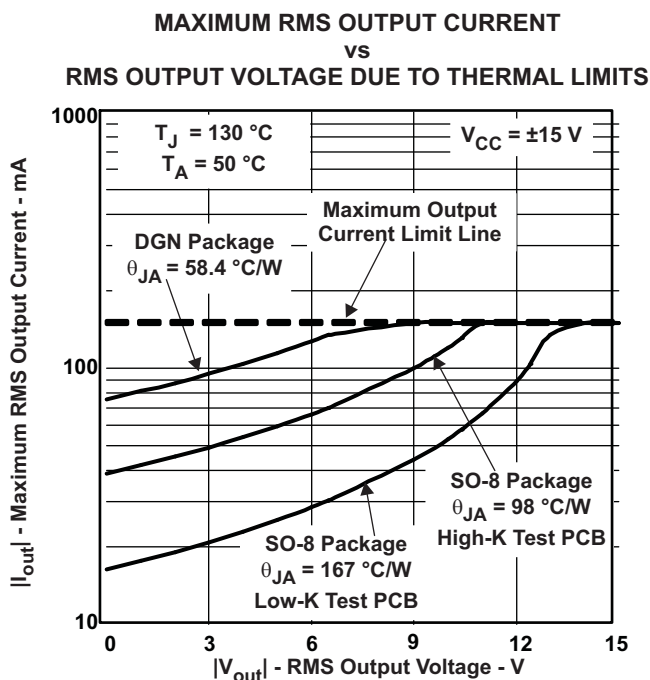


Figure 64.

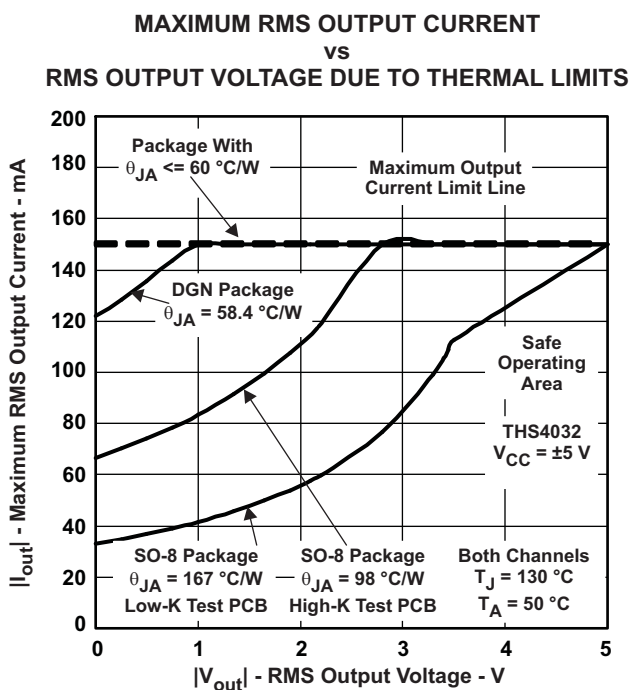


Figure 65.

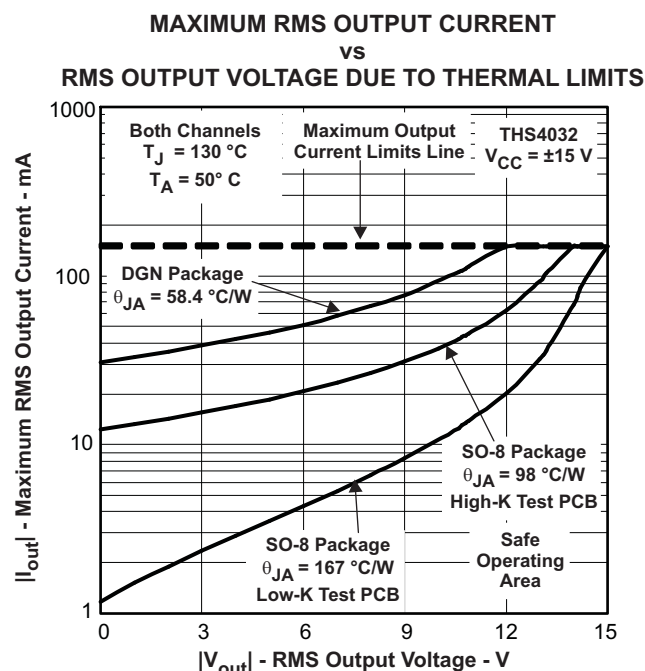


Figure 66.

EVALUATION BOARD

An evaluation board is available for the THS4031 (literature number [SLOP203](#)) and THS4032 (literature number [SLOP135](#)). This board has been configured for very low parasitic capacitance in order to realize the full performance of the amplifier. A schematic of the evaluation board is shown in [Figure 67](#). The circuitry has been designed so that the amplifier may be used in either an inverting or noninverting configuration. For more information, refer to the *THS4031 EVM User's Guide* ([SLOU038](#)) or the *THS4032 EVM User's Guide* ([SLOU039](#)). To order the evaluation board, contact your local TI sales office or distributor.

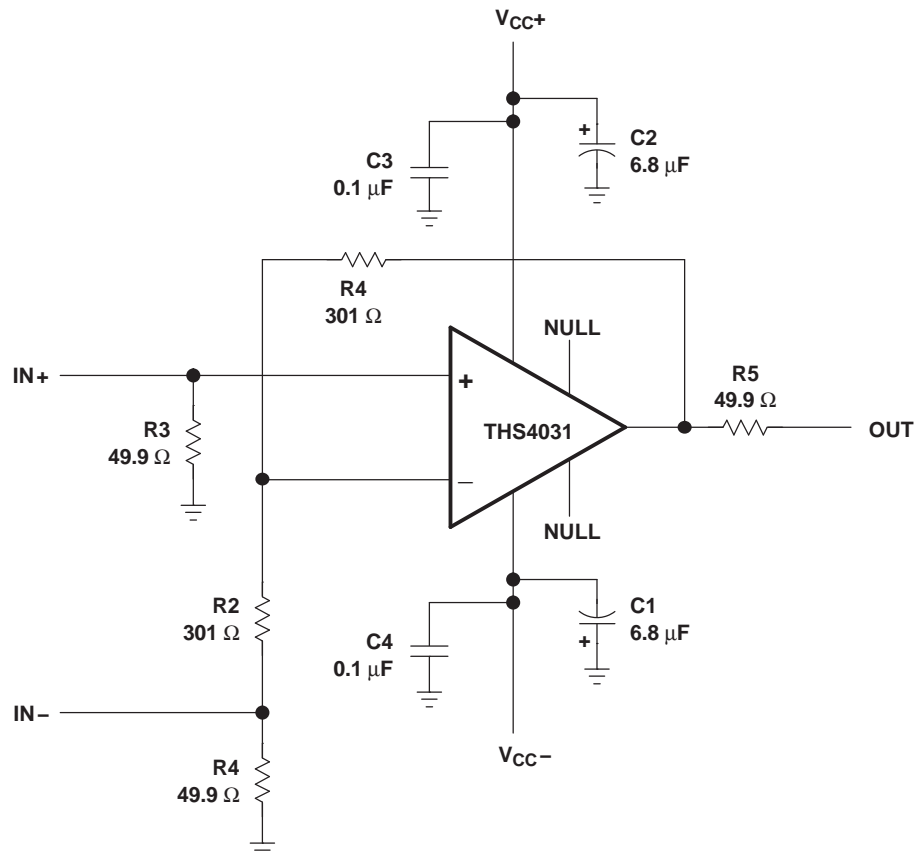


Figure 67. THS4031 Evaluation Board

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
THS4032MDGNREP	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	
V62/09612-01XE	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF THS4032-EP :

- Catalog: [THS4032](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4032MDGNREP	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4032MDGNREP	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0

DGN (S-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Falls within JEDEC MO-187 variation AA-T

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DGN (S-PDSO-G8)

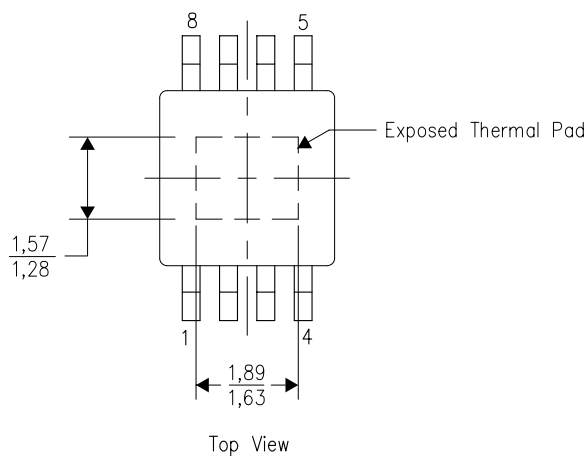
PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

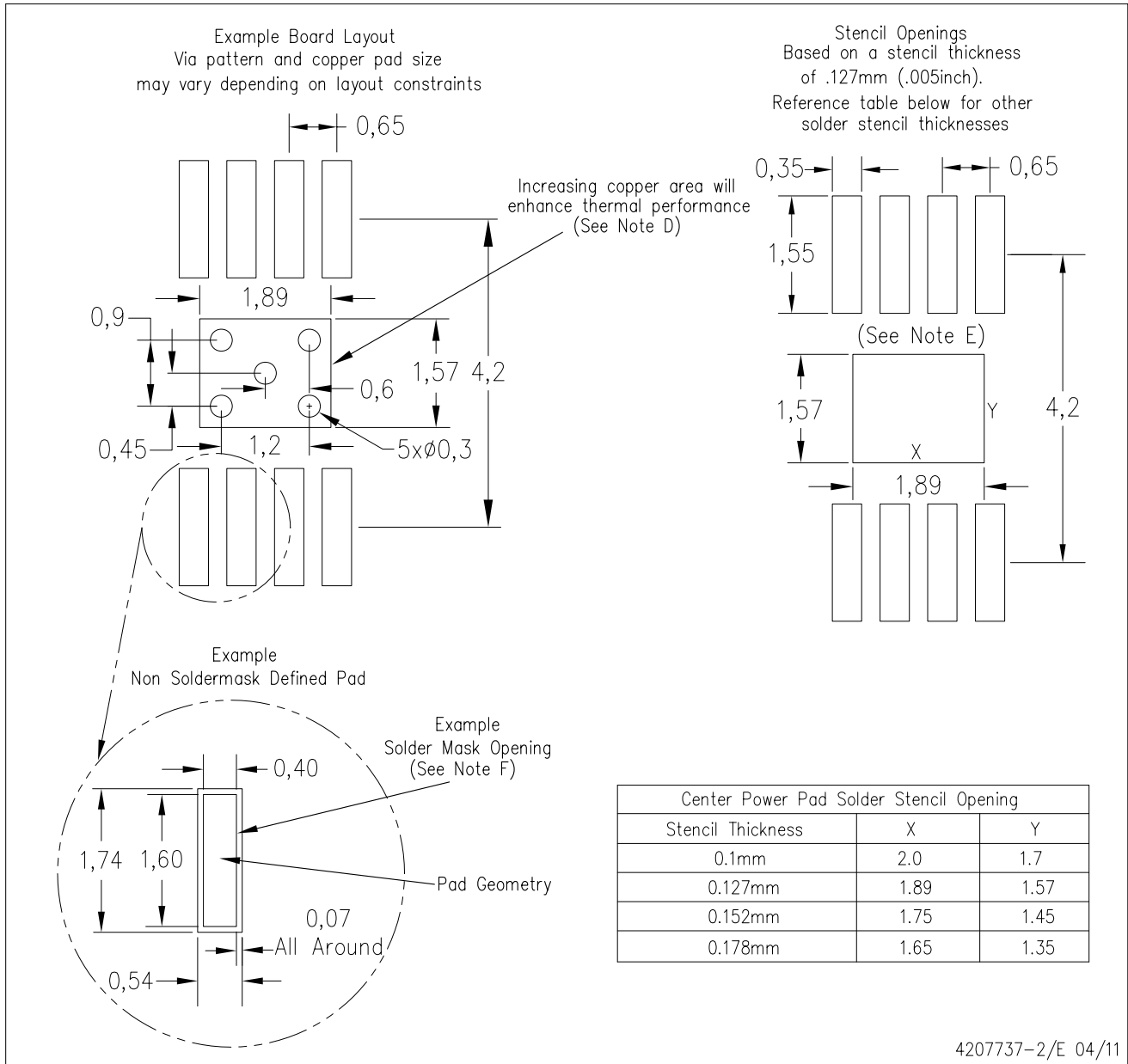


Exposed Thermal Pad Dimensions

4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters

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- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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